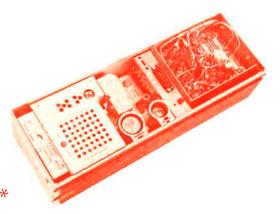


# MASTR Progress Line

406-470 MHz, 35 & 70-WATT TRANSMITTER MODELS 4ET59D30-41 & 4ET60D30-41



**SPECIFICATIONS** 

FCC Filing Designation:

Frequency Range:

Power Output:

Crystal Multiplication Factor:

Frequency Stability:

Modulation:

Audio Frequency Characteristics

Distortion:

Tubes & Transistors:

Maximum Frequency Spacing:

Duty Cycle:

Mobile-

Station-

ET-59-D-5

406-420 & 450-470 MHz

35 watts minimum (20 watts minimum in 6-volt systems)

36

 $\pm 0.0005\%$  (-35°C to +60°C)

Adjustable from 0 to ±5 kHz (Narrow Band) and 0 to  $\pm 15~\mathrm{kHz}$  (Wide Band) swing with instantaneous modulation limiting.

36

ET-60-D-5

70 watts minimum

406-420 &

450-470 MHz

Within +1 dB to -3 dB of a 6 dB/octave preemphasis from 300 to 3000 Hertz per EIA standards. Post limiter filter per FCC and EIA.

Less than 5%

Transmitter with no Options:

3 tubes

8 silicon transistors

4 diodes & 2 varactors

0.2%

20% transmit (one minute transmit, four minutes off)

Continuous

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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- WARNING -

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

## **DESCRIPTION**

The MASTR Progress Line FM Transmitters Types ET-59-D and ET-60-D are crystal-controlled, phase-modulated transmitters designed for one-, two-, or four-frequency operation within the 406-420 and 450-470 megahertz bands. The transmitters consist of the following modules:

- Transistorized Exciter Board, with audio, oscillator, modulator, amplifier and multiplier stages,
- Multipliers, IPA and power amplifier stages,
- Optional transistorized Channel Guard Low-Pass filter.

All input leads to the transmitters are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a two-section, band-pass filter, followed by a low-pass filter.

## **CIRCUIT ANALYSIS**

Eight silicon transistors and only three tubes are used in the transmitters. The frequency of the crystals used ranges from 11.25 to 11.67 and 12.5 to 13.05 megahertz, and the crystal frequency is multiplied 36 times.

A centralized metering jack (J102) is provided for use with General Electric Test Set 4EX3A10. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to audio, microphone and push-to-talk leads.

#### POWER INPUTS

The following supply voltages are connected from the power supply to the transmitter through the 20-pin by-pass connector J101:

- Pin 3 Filament voltage
- Pin 4 +300 volts MULT & IPA B+
- Pin 5 -45 volts bias
- Pin 14- +10 volts for Channel Guard option
- Pin 15- -20 volts for Exciter Board

### - NOTE -

The PA B-plus voltage will vary due to the different power supplies used (both mobile and station), and due to the power input limitations of different services. Refer to the PA Plate Voltage Chart on the Transmitter Schematic Diagram for the different operating conditions.

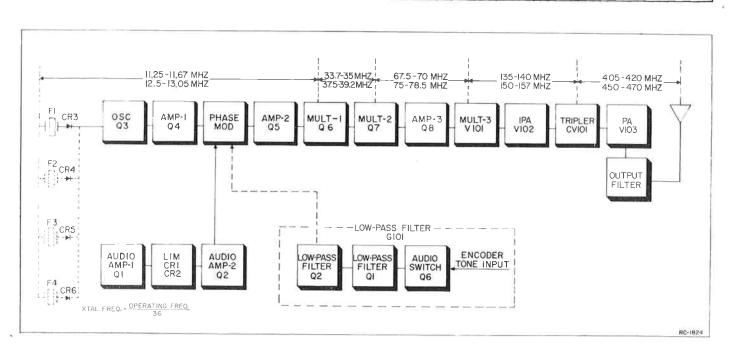


Figure 1 - Transmitter Block Diagram

#### OSCILLATOR

A transistorized Colpitts oscillator (Q3) is used in the transmitter. The oscillator crystal is thermistor-compensated at both ends of the temperature range to provide instant frequency compensation, with a frequency stability of  $\pm .0005\%$  without crystal ovens or warmers.

In single-frequency transmitters, a jumper (from H1 to H2) connects the F1 crystal keying lead to ground to forward bias diode CR3. Forward biasing the diode reduces its impedance, and the crystal frequency is applied to the base of oscillator Q3. Feedback for the oscillator is developed across C34/C35. The oscillator output is coupled through an impedance matching emitter-follower amplifier stage (Q4) to the phase modulator.

In multi-frequency transmitters, the single oscillator transistor is used, and up to three additional crystal circuits, identical to the Fl crystal circuit, can be added. The keying jumper is removed and the proper crystal frequency is selected by switching the crystal keying lead to ground by means of a frequency selector switch on the Control Unit.

#### AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through C1 to the base of Class A audio amplifier Q1. The design of the microphone, in conjunction with C2 and R3, produces a 6-dB audio pre-emphasis. RF decoupling is provided by C75.

The amplified audio signal is RC coupled to the diode limiters CR1 and CR2 These diodes operate in series and are normally in a forward conducting state. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R12 to a combined post-limiter filter and deemphasis network. This network consists of R15, R16, R17, C4, C7 and C8/C9. The output of the filter and deemphasis network is applied directly to the phase modulator.

## PHASE MODULATOR

The phase modulator uses varactor CV1 (voltage variable capacitor) in series with tuneable coil L1/L2. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CV1, resulting in a phase-modulated output. The output of the modulator is coupled

through blocking capacitor C41/C45 to the base of the second amplifier. For Channel Guard transmitters, a second modulator stage (L3/L4 and CV2) is cascaded with the first modulator. The output of the Channel Guard encoder is fed through CHANNEL GUARD MOD ADJUST R34 to the tone modulator stage.

#### AMPLIFIERS AND 1ST AND 2ND MULTIPLIERS

The second amplifier (Q5) isolates the modulator from the loading effects of the first amplifier and provides amplification. The output is DC coupled to the first multiplier.

Following Q5 are two inductively coupled Class C, common-emitter multiplier stages (Q6 and Q7). Q6 is a tripler, with collector tank T1 tuned to three times the crystal frequency. Metering resistor R37 is for metering the MULT-1 stage at centralized metering jack J102.

Q7 operates as a doubler stage, with collector tank T3 tuned to six times the crystal frequency. Resistor R39 is for metering the MULT-2 stage at J102. The output of Q7 is inductively coupled through T3 and T4 to amplifier Q8. In 450-470 megahertz transmitters, capacitor C58 provides some high-side capacitive coupling.

Third amplifier Q8 is a neutralized straight-through amplifier. Feedback through C65 from the output link on T5 provides neutralization. This stage is metered at J102-3 across R43. The output is coupled to the grid tank of multiplier V101.

## 3RD MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (Z101/Z102) of beam pentode V101. This stage operates as a doubler with the plate tank tuned to twelve times the crystal frequency.

Bias voltage (approximately -18 volts) is supplied to the grid of V101 through R108 to protect the tube against loss of drive. Grid voltage is metered by metering network R105 and R106 with a residual reading of approximately 0.18 volts without any drive, caused by fixed bias voltage to the grid of V101. The plate tank is tuned by C104 with plate voltage supplied through L101.

#### IPA AND TRIPLER

The output of the MULT-3 stage is coupled by a pi-network consisting of C104, L102/L103 and C107/C108 to the grid of the IPA, a compactron beam power amplifier.

Approximately 45 volts of bias voltage is supplied to the grid of V102 through R112 and a tap on L102/L103 to protect the stage

against loss of drive. A residual reading of 0.28 volt without any drive to the stage indicates the presence of fixed bias. Grid voltage and the tripler varactor bias voltage are metered simultaneously at J201-5.

The IPA plate tank is tuned by C115, and plate voltage is supplied through L105. The stage is neutralized by C110.

RF from the IPA is coupled through C118/C119 to a passive tripler stage. The tripler consists of three tuned stages (C115 & L107/L108, C121 & L110/L111, and C122 & L112/L113) which are coupled together through the common impedance of varactor CV101.

The IPA output is fed to the tripler, where the first tuned stage resonates at the fundamental frequency. The second tuned circuit (an "idler" circuit) is tuned to twice the input signal, and mixes with the input signal to produce the desired third harmonic (or operating frequency). The third tuned circuit is tuned to the operating frequency.

#### POWER AMPLIFIER

Drive from the tripler stage is link-coupled to the grid circuit of V103 through L115 and L116. V103 is a coaxial element, conduction-cooled beam power tetrode operating as a neutralized Class C amplifier.

The grid line L127/L128 of V103 is series-tuned by C130 with 20 volts of protective bias supplied through L117 and grid bias resistors R103 and R129. PA grid current is metered across resistor R103 at J102-6 and J102-14.

Neutralization is provided by a fixed series screen inductance (the fingers on the screen by-pass ring) and the screen by-pass capacitors C135, C136, C138 and C140.

The PA Plate tank circuit is comprised of C145 (the plate tank tuning flap), L119/L120 (the copper-plated heat sink on the plate of V103), and mechanically constructed capacitor (with mica dielectric) C143. The plate voltage is supplied through choke L122, which is connected to feed-through capacitor C142.

The PA screen voltage is controlled by OUTPUT CONTROL potentiometer R124 which is in series with R123/R126 in the screen supply circuit. With the OUTPUT CONTROL fully counterclockwise, the plate dissipation of V103 is reduced below the rated tube limit for tuning the power amplifier stage.

Plate current is metered from J102-1 to J102-9 across metering resistor R102 in high-power units. In medium-power units, R101 is added in series with R102.

WARNING -

The meter leads are at plate potential (high B-plus) when metering the PA Plate.

The output of V103 is link-coupled to band-pass filter FL101/FL102 consisting of two inductively coupled helical resonators. C1/C2 and C3/C4 are the output tuning capacitors. L5/L6, C5 and C6 form an additional low-pass filter section. The RF output is fed through J103 to the antenna changeover relay located on the front of the system frame.

An RF sniffer circuit (CR1, C7, and R1) provides for measuring the relative power output at J102-11. When troubleshooting the transmitter, components of the low-pass filter and RF sniffer circuit can be checked by removing the plate on the bottom of the filter casing.

#### CHANNEL GUARD

### Low Pass Filter (G101)

In encode-decode combinations, low-pass filter G101 is assembled on a printed wiring board that mounts on the underside of the MASTR transmitters. The filter is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied only when the transmitter is keyed.

Keying the transmitter applies the encoder tone (from the receiver) to low-pass filter G101. Transistors Q1 and Q2 form a two-section, active low-pass filter that reduces tone distortion and power supply Q6 operates as a tone switch, apripple. plying the tone input to the filter whenever +10 volts is applied to J1 (Q6 base). Thermistor RT1 keeps the output constant over wide variations in temperature. filter output is coupled to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. structions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

NOTE .

When Channel Guard decode only is desired, remove the wire that connects to J6 on the low-pass filter (Encoder Tone Input).

## Encoder Model 4EH17A10 (Optional)

In encode only combinations, or when different encode and decode frequencies are required, optional encoder Model 4EH17A10

mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied to Q3, Q4 and Q5 continuously (even in the STANDBY position). The -20 volts is applied to Q1 and Q2 only when the transmitter is keyed.

The encoder tone is provided by selective oscillators Q3 and Q4, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q3, prevents any gain in the stage except at the desired encode frequency.

Thermistor-resistor combination R14 and RT2 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

Keying the transmitter applied -20 volts to the two-stage, active low-pass filter (Ql and Q2) turning them on. The oscillator output is then coupled through emitter-follower Q5 to the low-pass filter. Thermistor RTl keeps the filter output constant over wide variations in temperatures.

The output of the filter is applied to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

## MAINTENANCE

#### DISASSEMBLY

To service the transmitter from the top--

- Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of transmitter.

To service the transmitter from the bottom--

- Pull locking handle down and pull radio out of mounting frame.
- Remove the two screws in bottom cover, and pry up at back of transmitter.
- 3. Slide cover back and lift off.

To remove transmitter from system frame--

- 1. Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.
- 2. Remove the four screws in the back cover.
- Remove the two screws holding the transmitter at each end of the system frame.

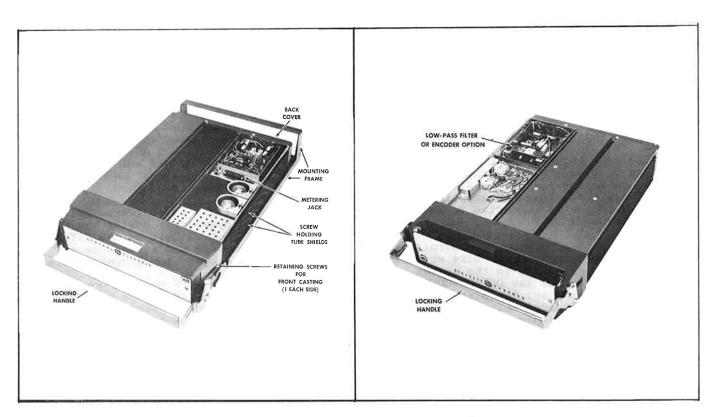


Figure 2 - Top Cover Removed

Figure 3 - Bottom Cover Removed

4. Disconnect the antenna jack in front of the transmitter and the 20-pin feed-thru connector at the back of the transmitter, and slide the unit out of the system frame.

#### TUBE REPLACEMENT

WARNING -

Before replacing tubes, remove all power from the unit so that the transmitter cannot be keyed. In mobile units, disconnect power plug P504. In stations, turn off the main line switch and discharge filter capacitors.

# To replace 3rd Multiplier and IPA Tubes (V101 & V102)

Loosen the two screws holding tube shield to heatsink, and pull off tube shield. Then carefully work the tube out of its socket.

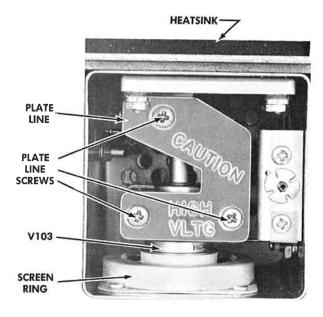


Figure 4 - PA Plate Box With Cover Removed

To replace Power Amplifier V103:

- Make sure that all power is removed from the unit.
- 2. Remove the top cover on the AMPL PLATE box (fig. 4). Allow the transmitter to cool if necessary.
- 3. Remove the three Phillips-head screws in the plate line, starting with the two screws nearest tube socket. Lift off the top section of the plate line. Next, slide the bottom section toward the AMPL PLATE tuning adjustment and lift it out of the AMPL PLATE box.
- 4. Carefully work the tube out of its socket.
- 5. Use a screwdriver to bend the screen ring contacts out toward the center of the tube socket so that all contacts will touch the base of the tube.

#### CAUTION \_

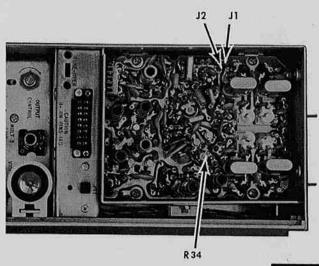
Extreme care should be taken during PA tube replacement to avoid damaging the screen ring contacts.

- 6. Replace the tube by hand, making sure that it is fully seated in the socket and that all screen ring contacts are touching the tube.
- 7. Replace the plate lines, tightening the screw nearest the heatsink first. Then replace the top cover of AMPL PLATE box.
- 8. Realign the transmitter.

.mum reading as shown in power output chart

ting Procedure.

ransmitter as shown below:



.tter Exciter

ion (1.5 kHz t Channel Guard



**DEVIATION METER** 

for deviations up to 2.4 kHz for tone s up to 3.0 kHz for all tone frequencies

se Modulator Tuning should be peaked careo Steps 1 and 2 in the Transmitter Align-

repeated everytime the Tone Frequency is

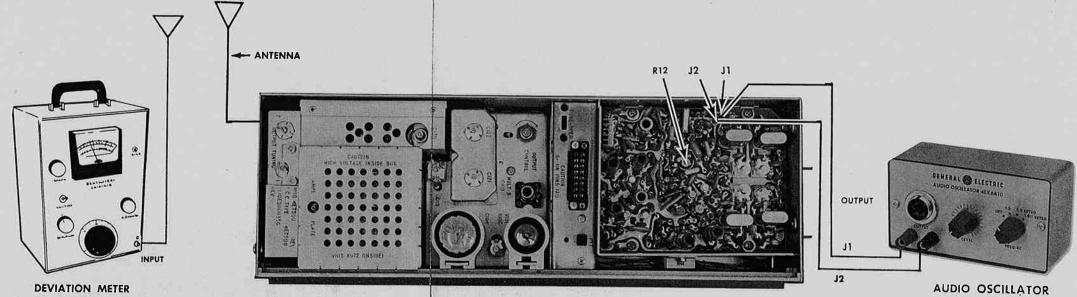
## SERVICE CHECK

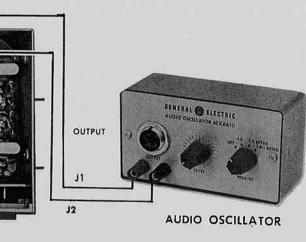
If the 0.75 kHz (1.5 kHz wide-band) deviation is not obtainable when adjusting R34, replace the encoder tone network.

# STEP 3

# VOICE DEVIATION AND SYMMETRY **TEST PROCEDURE**

- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- 2. Connect test equipment to transmitter as shown below:





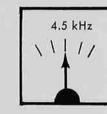
- Set the generator output to 0.75 VOLTS RMS and frequency to 1 kHz.
- Key the transmitter and adjust Deviation Meter to carrier frequency.
- Deviation reading should be ±4.5 kHz (±13 kHz wide-band).
- Adjust "Modulation Adjust Control" R12 until deviation reads 4.5 kHz (13 kHz wide-band) on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.

NOTES: --MASTR transmitters are adjusted for 4.5 kHz (13 kHz wide-band) deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5 kHz (15 kHz wide-band) under the worst conditions of frequency, voltage and temperature.

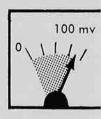
If the deviation reading plus (+) and minus (-) differs by more than 0.5 kHz (1.5 kHz wide-band), check the following:

- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- 2. Check Audio Sensitivity by reducing generator output until deviation falls to 3.3 kHz (10 kHz wide-bar Voltage should be LESS than 100 millivolts.

**DEVIATION METER** 



METER



# **TEST PROCEDURES**

These Test Procedures are designed to assist you in servicing a transmitter that is oper- a defect is pin-pointed, refer to the "Service ating--but not properly. Problems encountered could be low power output, low B plus, tone and voice deviation, defective audio sensitivity and modulator adjust control set too high. By follow- ter Test Procedures, be sure the transmitter is ing the sequence of test steps starting with Step tuned and aligned to the proper operating fre-

1, the defect can be quickly localized. Once Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitquency.

## TEST EQUIPMENT REQUIRED

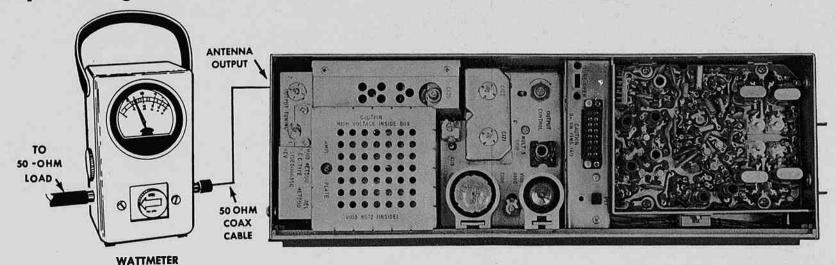
for test hookup as shown:

- 1. Wattmeter similar to: 2. VTVM similar to: Bird #43 Triplett #850
- 3. Audio Generator similar to: 4. Deviation Meter GE Model 4EX6A10 or Heath #1G-72
- similar to: Measurements #140
- 5. Multimeter similar to: GE METERING TEST SET MODEL 4EX3A10, 4EX8K11, Triplett #631 or 20,000 ohms-per-volt voltmeter

## STEP 1

# POWER MEASUREMENT TEST PROCEDURE

Connect transmitter output to wattmeter as shown below, using a low-loss coaxial cable between the antenna jack and wattmeter. RG-303/U is recommended for accurate power output readings.



Key transmitter and check wattmeter for minimum re on Transmitter Schematic Diagram.

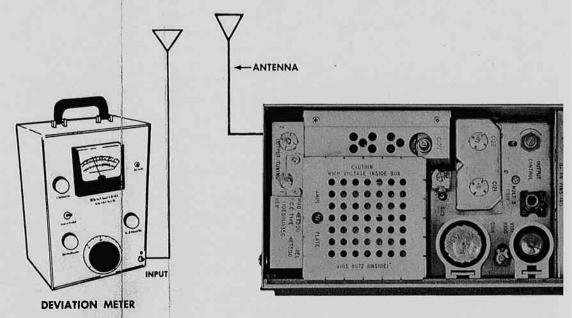
## SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Pr

## STEP 2

# TONE DEVIATION WITH CHANNEL GUARD TEST PROCEDURE

Setup Deviation Meter and monitor output of transmi



- Unplug the MIC HI terminal from Jl on Transmitter H Board.
- Key transmitter and check for 0.75 kHz deviation () wide-band). If reading is low or high, adjust Char MOD ADJUST (R34) for a reading of 0.75 kHz.

## NOTES:

The Channel Guard MOD ADJUST (R34) may be adjusted for d frequencies from 71.9 Hz to 82.5 Hz, and deviations up t above 82.5 Hz.

- On units supplied with Channel Guard, the Phase Mod fully to insure proper performance. (Refer to Step ment Chart).
- The Tone Deviation Test Procedures should be repeat changed.

#### EQUIPMENT REQUIRED

1. General Electric Test Set Models 4EX3AlO (TMll or TMl2), 4EX8Kll, Station Test Meter Panel, or a 20,000 ohms-per-volt Multimeter with a 1-volt scale.

#### PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place crystal (operating frequency + 36) in crystal socket XY1.
- 2. For a badly mis-aligned transmitter or a large change in frequency, set crystal trimmer C10 to mid-capacity. If multi-frequency transmitter, set all trimmers to mid-capacity and tune transmitter on channel with the lowest frequency (except for Steps 15 and 16).
- 3. Turn OUTPUT CONTROL (R124) fully counterclockwise. This limits PA dissipation during initial tune-up.
- 4. Connect Test Set Model 4EX3AlO to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground), except where indicated.
- 5. For a large change in frequency or a badly misaligned transmitter, set the slugs in the Exciter coils at the bottom of the coil form, and the slug of Z101/Z102 (MULT-3 GRID) at the top of the coil form. Tune AMPL PLATE counterclockwise until the stud is even with the top of the case. Then turn C121, C122 and OUTPUT TUNING -1 and -2 fully counterclockwise
- 6. All adjustments are made with the transmitter keyed.

#### ALIGNMENT PROCEDURE

STEP	METERIN 4EX3A10	G POSITION Multimeter - at J102	TUNING CONTROL	TYPICAL METER READING	PROCEDURE
				EXCITE	R BOARD
1.	A (MULT-1)	Pin 10	L1/L2 (and L3/L4 with Channel Guard)	0.8 v (0.5 v Minimum)	Tuning the modulator is a critical adjustment. Carefully tune L1/L2 for maximum meter reading. For transmitters with Channel Guard, alternately tune L1/L2 and L3/L4 for maximum meter reading.
2.	A (MULT-1)	Pin 10	Tl	See Pro- cedure	Tune Tl for a small peak in meter reading (not required unless changing frequency).
3.	B (MULT-2)	Pin 2	T2, T1 and T3	0.65 v (0.5 v Minimum)	Tune T2 and then T1 for maximum meter reading. Then tune T3 for minimum meter reading (not required unless changing frequency).
4.	C (AMPL-3)	Pin 3	T4, T3 and T5	0.60 v (0.5 v Minimum)	Tune T4 and then T3 for a maximum meter reading. Then tune T5 for minimum meter reading (not required unless changing frequency).
			N	MULT-3, IPA	AND POWER AMPLIFIER
5.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102)	0.6 v (0.5 v Minimum)	Tune MULT-3 GRID for maximum meter reading.
6.	C (AMPL-3)	Pin 3	Т4	Maximum	Retune T4 for maximum meter reading.
7.	D (MULT÷3)	Pin 4	MULT-3 GRID (Z101/Z102)	Maximum	Retune MULT-3 Grid for maximum meter reading.
8,	E (MULT-4)	Pin 5	IPA GRID (C104) & C115	Maximum	Tune IPA GRID for maximum meter reading. Then tune Cll5 for maximum meter reading (not required unless changing frequency).
9.	E (MULT-4)	Pin 5	C121 & C122	See Pro- cedure	Tune C121 clockwise until meter reading drops abruptly. Then turn C122 clockwise for a change in meter reading. This step is not required unless changing frequency.
10.	F PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130) & C115, C121 & C122	See Pro- cedure	Tune AMPL GRID for maximum meter reading. Then retune C115, C121, C122 and AMPL GRID in that order until no further increase in meter reading is noted.
11.	G PA PLATE	WARI High B+ on Pin 1 (+) Pin 9 (-)	NING Pins 1 & 9 AMPL PLATE	Minimum	Tune AMPL PLATE for a dip in meter reading (not required unless changing frequency).
12.	H REL PWR OUT	Pin 11	OUTPUT TUNING -1 & -2 and AMPL PLATE	Maximum	Alternately tune OUTPUT TUNING -1 and -2 and AMPL PLATE in that order for maximum meter reading.
13.	G PA PLATE	Pin 1 (+) Pin 9 (-)	OUTPUT CONTROL (R124)	See Pro- cedure (See note 1)	Adjust OUTPUT CONTROL for a meter reading of 0.7 volt (0.6 volt for continuous duty stations).
14.					Repeat Steps 12, 13 and 10 in that order

STEP	METERII 4EX3A10	Multimeter - at J102	TUNING	CONTROL	TYPICAL METER READING	PROCEDURE
				FOR	MULTI-FREQU	ENCY UNITS ONLY
15.	PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130)		See Pro- cedure	After completing Steps 1 thru 14 using the lowest channe: frequency, alternately switch from the highest to the lowest frequency and tune AMPL GRID for equal meter readings.
16.	H REL PWR OUT	Pin 11	OUTPUT TU		See Pro- cedure	Alternately switch from the highest to the lowest frequency and tune OUTPUT TUNING-1 and AMPL PLATE for equal meter readings.
					FREQUENCY	ADJUSTMENT
17.						With no modulation, adjust crystal trimmers C10, C16, C22 or C28 as required. Next, refer to the MODULATION ADJUSTMENT.

## REDUCED POWER OPERATION

- NOTE 1 In some services, FCC regulations do not permit the use of full rated power input to the PA Plate circuit. In such cases:
  - 1. In station applications, make sure that the power transformer taps are set for the PA Plate voltage shown in the Maintenance Manual for Power Supply Type EP-38-A.
  - 2. In mobile applications, make sure that the transformer taps are set as shown in the Maintenance Manual for the 4EP37A10, 4EP37B10, 4EP37C10 or 4EP37D10.
  - 3. Adjust the OUTPUT CONTROL for the meter reading shown in the following chart.

	XMTR	MEASURED	METER
	TYPE	PLATE VOLTAGE	READING
For 60-Watt Input	ET-59-D	275 to 305 VDC (see Note 2)	0.7 VDC
For 120-Watt	ET-60-D	460 to 510 VDC	0.7 VDC
Input		(see Note 3)	MAX.

NOTE 2 - If the plate voltage is not within the 275 to 305-volt limit, find the OUTPUT CONTROL setting by dividing 210 by the measured plate voltage.

Meter reading in volts =  $\frac{210}{\text{Measured Plate Voltage}}$ 

NOTE 3 - If the Plate Voltage is not within the 460 to 510-volt limit, find the OUTPUT CONTROL setting by dividing 311 by the measured plate voltage.

Meter reading in volts = Measured Plate Voltage

# ALIGNMENT PROCED

406—470 MHz, 35 & 60-WATT 1 TRANSMITTER MODELS 4ET59D30-MODELS 4ET60D

## **MODULATION LEVEL ADJUSTMENT**

The MOD ADJUST (R12) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

#### TEST EQUIPMENT

- 1. An audio oscillator
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Model 4EX3A10

#### PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across J1 (Mike High) and J2 (Mike Low) on the Exciter Board.
- 2. Apply a 0.75-volt signal at 1000 Hz  $\,$  to Test Set or across J1 and J2 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R12) for a 13 kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R34) for 1.5 kHz tone deviation. Then repeak L1/L2 and L3/L4 as shown in Step 1 of Transmitter Alignment Procedure. Reset tone deviation to 1.5 kHz deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 1.0 volt signal at 1000 Hz and set MOD ADJUST (R12) for 11.5 kHz deviation (13 kHz minus 1.5 kHz tone deviation).
- 5. For multifrequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

## PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

ET-59-D: 
$$P_i = \frac{Plate\ Voltage\ x\ Plate\ Current\ Indication}{3.5}$$

ET-60-D: 
$$P_i = \frac{Plate\ Voltage\ x\ Plate\ Current\ Indication}{2.59}$$

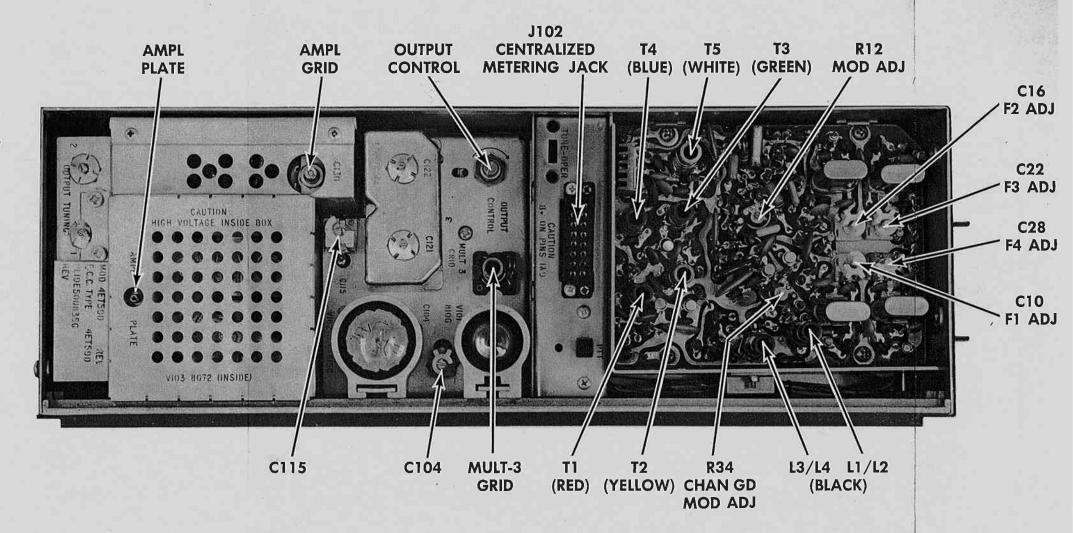
## Where:

Pi is the power input in watts.

Plate voltage is measured with GE Test Set in position G, using the 1000-volt scale (or measured from J102-1 to -16 with multimeter).

Plate current indication is measured with GE Test Set in Position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

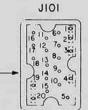
3.5 or 2.59 is the value of the plate current metering resistor in ohms.



CI58 () () () () () () () () () () () () () (
- 4

PIN	-	+
- 1	0	0
2	œ	00
3	10	. ιΩ
4	19K	19 K
5	00	00
6	000	00
7	00	00
8	50K	50K
9	00	000
1.0	00	00
11	~	~
12		
13	00	00
14	00	000
15	5,5 K	2.5K
¥ 16	∞/30K	∞/15 K
¥ (7	∞/30K	∞/15 K
¥ 18	∞/30K	∞/15K
19	0	0
20	00	00

\* IST READING FOR SINGLE FREQ. 2ND READING FOR MULTI-FREQ.



## RESISTANCE READINGS

ALL READINGS ARE TYPICAL READINGS MEASURED WITH A 20,000 OHM-PER-VOLT METER AND JIOI DISCONNECTED. + OR — SIGNS SHOW METER LEAD GROUNDED. OUTPUT CONTROL FULLY COUNTER-CLOCKWISE AND ALL TUBES IN THEIR SOCKETS.

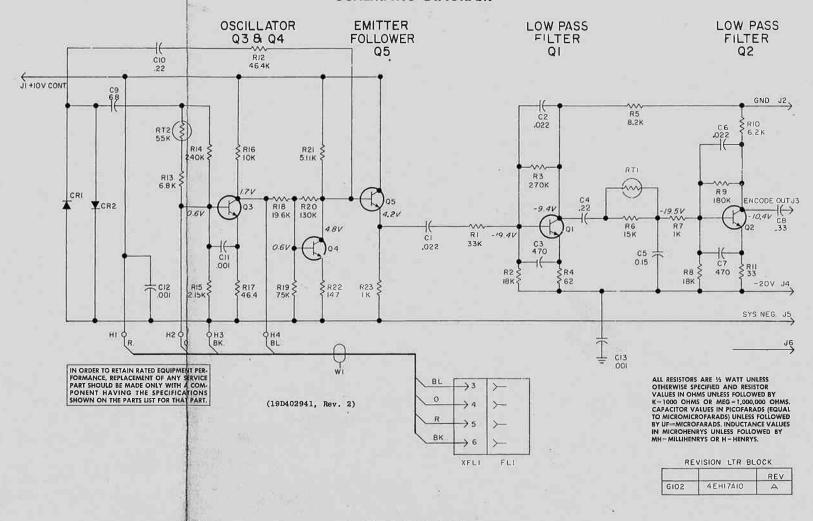
FOR READINGS OF: USE SCALE:

 $\begin{array}{c} \text{I-IOO}\,\Omega\\ \text{IOO-IK}\,\Omega\\ \text{IK-50K}\,\Omega\\ \text{50K-}\infty\,\Omega \end{array}$ X 10 X 1,000 X 100,000

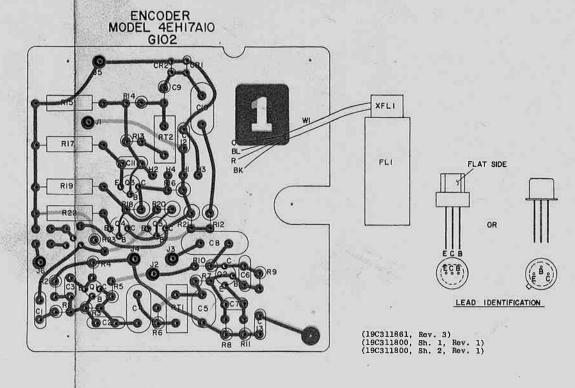
READING	SS TAKEN	FROM	TUBE SOCKE	I PINS	TO CHASS	IS GROU	INU					
PIN	1	2	3	4	5	6	7	8	9	10	1.1	12
XVIOI	20K	0	46 K	IΩ	0	0	32K	46K	0			
XVI02	IΩ	0	19 K	19 K	19K	0	24K	0	0	55K	24 K	C
XVI03	0	00	2K/6K *	0	0	12	12.5 K	2K/6K*	0	00	2K/6K*	

# CHANNEL GUARD ENCODER MODEL 4EH17A10

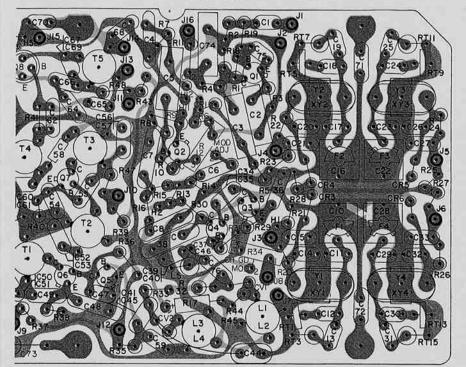
## SCHEMATIC DIAGRAM



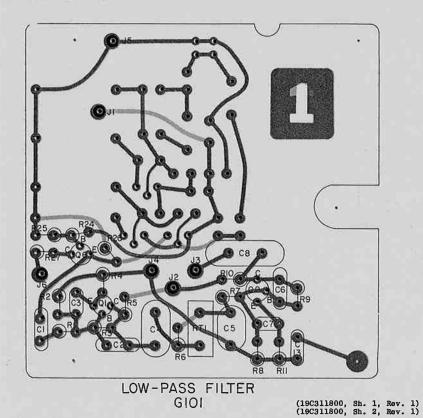
## **OUTLINE DIAGRAM**



EXCITER AIOI-AII2

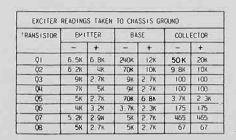


303483, Sh. 1, Rev. 7) 303483, Sh. 2, Rev. 7)

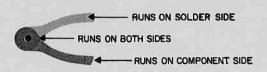


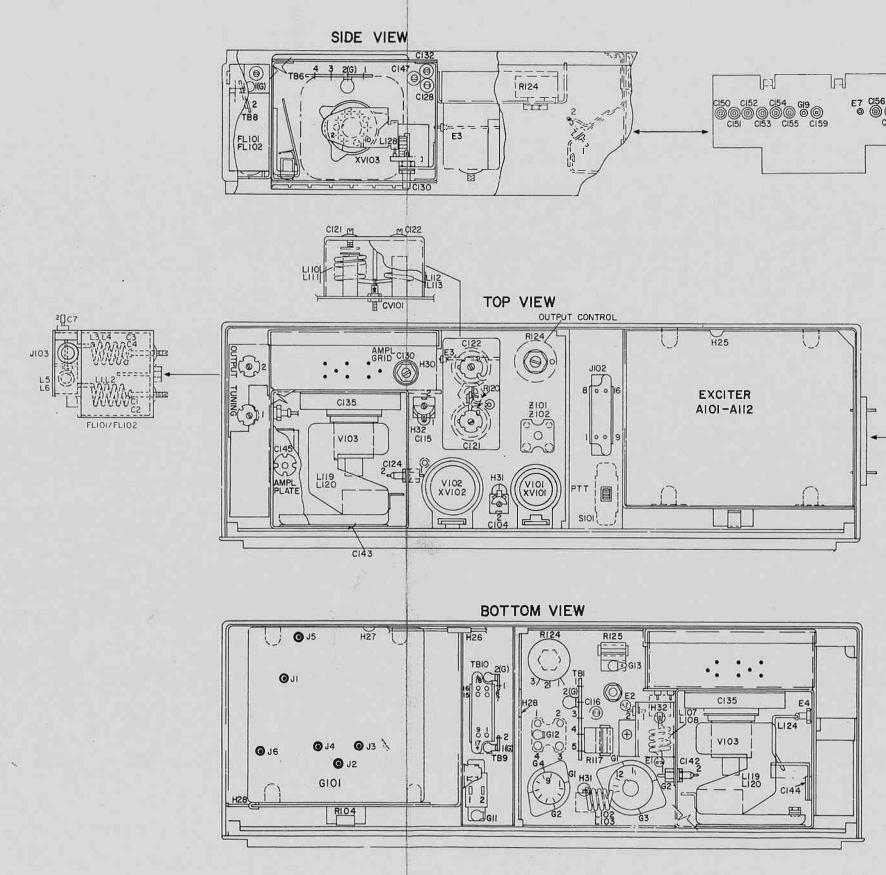
# **JTLINE DIAGRAM**

6-470 MHz, 35 & 60-WATT TRANSMITTER DELS 4ET59D30-41 & 4ET60D30-41

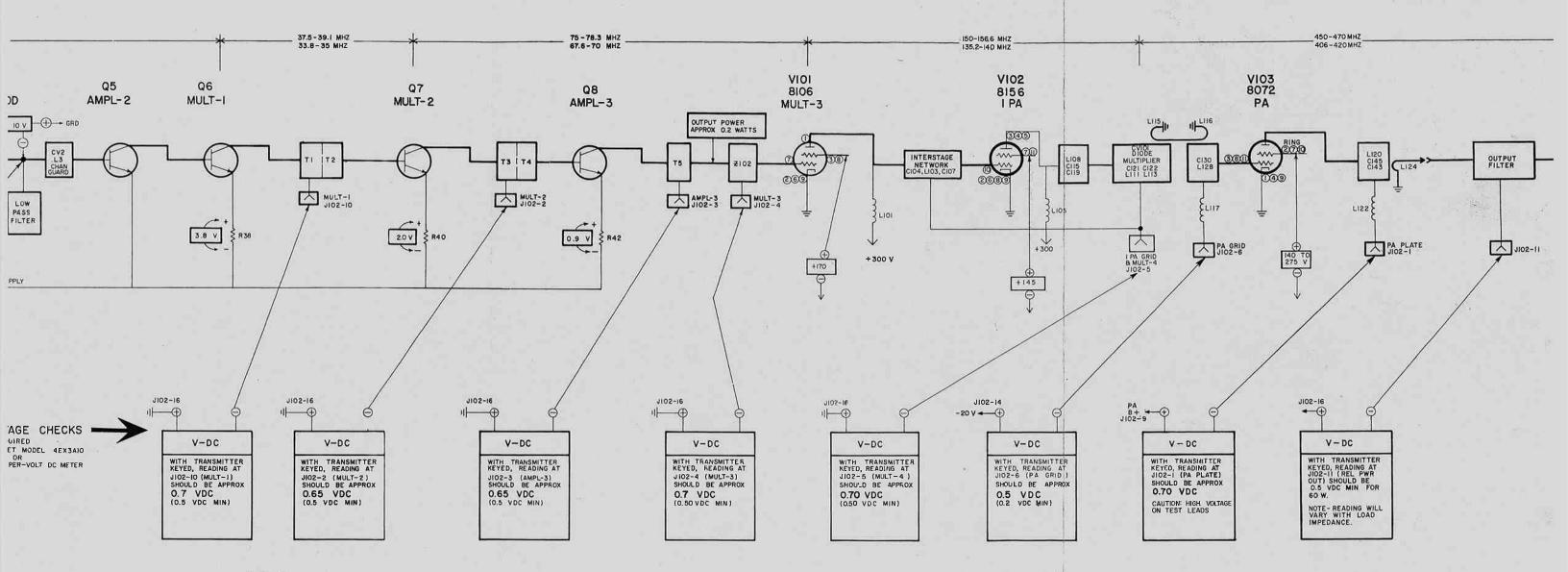


TRANSISTOR	EMI	TTER	BAS	E	COLL	ECTOR
	-	+ "	-	+		+ 1
Q1	LIK	14K	240k	30ĸ	60k	35K
Q2	IK	IK	70K	4.3k	148	18K
03	2.6K	2.5K	IOK	5 5K	2 7h	5.1X
Q4	1.5K	Г:5к	2 6K	2 5K	2 7K	5. IK
Q5	0	.0	70K	3.2K	8.2k	3 8k
Q6	340	360	8h	3 8K	3к	5 IX:
07	60	180	0	0	2.3K	5.5k
Q8	27	27	47	47	2.6K	5K





(19R621286, Rev. 3)



RC-1462A

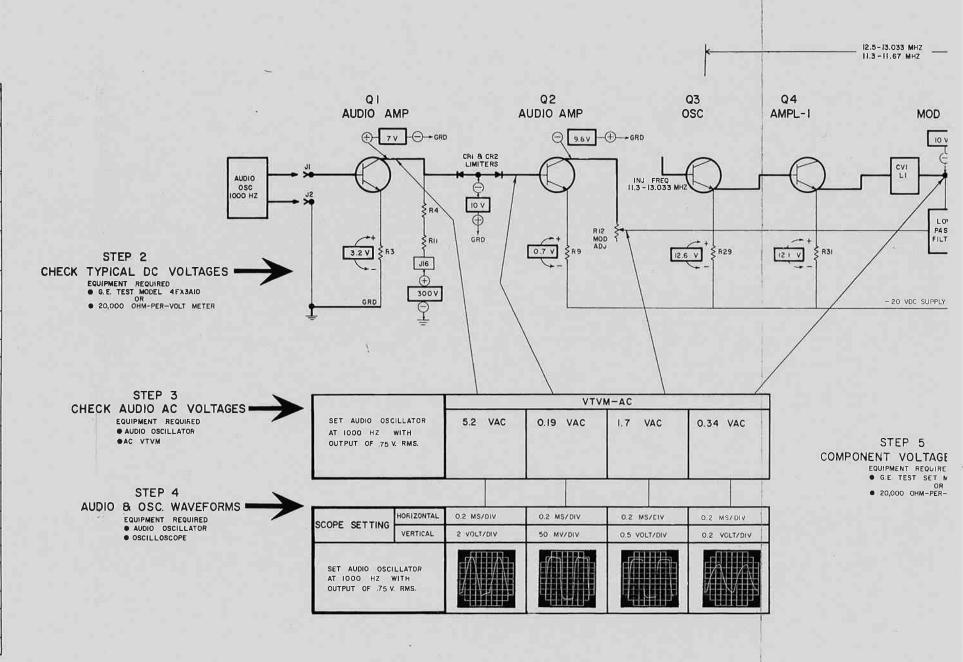
# TROUBLESHOOTING PROCEDI

406-470 MHz, 35 & 60-WATT TRANSMI' MODELS 4ET59D30-41 & 4ET60D3

Issue 1

# STEP I - QUICK CHECKS

POWER		CHE		Multimet	er = pin	numbers	ING JACK	
OUTPUT			G	E Test S	et = A-G	positio	ns	PROBABLE DEFECT
	Pins 10 & 16 A	Pins 2 & 16 B	Pins 3 & 16 C	Pins 4 & 16 D	Pins 5 & 16 E	Pins 6 & 14 F	Pins 1 & 9 G	
0	0	0	0	0.18 v	0,28 v	0	Low	Defective Q3-Q6 or Modulator (see Note A)
0	over 1.0 v	0	0	0.18 v	0.28 v	0	Low	Shorted Q5 or open Q6
0	0.70 v	0 or over 1.0 v	0	0.18 v	0.28 v	0	Low	Defective Q7
0	0.70 v	0.65 v	0 or over	0.18 v	0.28 v	0	Low	Defective Q8
0	0.70 v	0.65 v		0.18 v	0.28 v	0	Low	Open filament on 8106, open coax
0	0.70 v	0.65 v	0.7 v	0.75 v	0.28 v	0	Low	Open filament on 8156
0	0.70 v	0.65 v	0.7 v	0.75 v	0.75 v	0	0	Open filament on 8072
0	0.70 v	0.65 v	0.7 v	0.75 v	0.5 v	0	0	If no peak at position "E" when tuning C115, bad multiplier diode or 8156
0	0.72 v	0.65 v	0.7 v	0.75 v	0.75 v	high	Very Low or O	Bad R123/R126, bad R124, shorted 8072 screen
Low	0.72 v	0.65 v	0.7 v	0.75 v	0.75 v	Low	0.70 v	Weak 8156 or 8072
Erratic	0.72 v	0.65 v	0.7 v	0.75 v	0.75 v	Very high	0.70 v	Check contacts on screen bypass ring
NOTE A -	Loca	lize tro	uble by	checking	:			
1.	-20	volt DC	supply a	t J102-1	2-16.			
2.								0 ohms), then:
(a)				light va properly		in R31 v	oltage r	reading indicates Q3 and
(b)	If no	voltag	e is mea	sured, c	heck key	ing lead	ls CR3-CR	R6, Q3, Q4.
(c)	With volt	crystal indicat	removed es Q5 an	l, short d Q6 are	Q5 base operati	to emitt	er. A verly. De	oltage reading above 1.0 efect may be in Modulator.
(d)	If m	odulator	is defe	ctive, c	heck vol	tage var	iable di	odes CV1 and CV2.



## PARTS LIST

LBI-4025D

405-470 MHz TRANSMITTER

MODELS 4ET59D30-35 STANDARD
MODELS 4ET59D36-41 CHANNEL GUARD
MODELS 4ET60D30-35 STANDARD
MODELS 4ET60D36-41 CHANNEL GUARD

Ali2 Ali2 Ali2 Ali2 Ali2 Ali2 Ali3 19h0230862 ARTS9D31, 4ET60D31 2 Fre Ali6 19h0230863 4ET89D31, 4ET60D32 2 Fre Ali6 19h0230863 4ET89D33, 4ET60D36 1 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 2 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 2 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 2 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 1 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 1 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 2 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 1 Fre Ali6 19h0230863 4ET89D39, 4ET60D36 2 Fre Ali6 19	SYMBOL	GE PART NO.	DESCRIPTION
C1 19A116080P3 Polyester: 0.022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: 0.33 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 0.0022 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P5 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: 0.47 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 0.0016 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 5493367P1000K Silver mics: 0.01 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20. C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C12 and c13 C14 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C15 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RWC Type JF Discap. C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C20 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C21 5494481P111 Recramic disc: .001 pf ±20%, 1000 VDCW; sim to RF Type JF Discap. C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C23 5496219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EF Johnson 189. C24 19C300685P93 Ceramic disc: .01 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C25 5496219P751 Ceramic disc: .01 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C26 5496219P751 Ceramic disc: .01 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C27 5494481P111 Ceramic disc: .01 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C28 5496219P751 Ceramic disc: .01 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C29 5496219P751 Ceramic disc: .01 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C29 5496219P751 Ceramic disc: .01 pf ±10%, 1000 VDCW; sim to EF Johnson 189-6-5. C29 5496219P7 Ceramic disc: .01 pf ±10.5 pf, 500 VDCW, temp coef 0 PPM. C30 18C300685P93	thru		A101 190402308G1 4ET69D30, 4ET60D30 1 Freq A102 190402308G2 4ET59D31, 4ET60D31 1 Freq A103 190402308G3 4ET59D32, 4ET60D32 2 Freq A104 190402308G4 4ET59D33, 4ET60D33 2 Freq A105 190402308G5 4ET59D34, 4ET60D35 4 Fred A107 190402308G7 4ET59D35, 4ET60D35 1 Freq A107 190402308G7 4ET59D36, 4ET60D36 1 Freq A109 190402308G9 4ET59D36, 4ET60D37 1 Freq A109 190402308G9 4ET59D36, 4ET60D37 2 Freq A109 190402308G10 4ET59D36, 4ET60D36 2 Freq A110 190402308G10 4ET59D36, 4ET60D36 2 Freq A111 190402308G10 4ET59D36, 4ET60D37 2 Freq
C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 0.0022 pf ±10%, 500 VDCW; sim to RMC Type Jh. C5 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RMC Type Jh. C8 5493367P1000K Silver mics: .001 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20. C10 5491271P108 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C12 19C300685P83 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C15 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C19 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C21 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C23 5495219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C25 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 37 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 549621			
C3 19A116080P7 Polyester: 0.1 μf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 0.0022 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: 0.47 μf ±20%, 50 VDCW. C6 19A116080P5 Polyester: 0.47 μf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 5493367P1000K Silver mica: .001 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5491271P106 Silver mica: .001 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20. C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C12 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C15 5494481P11 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C16 5495219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C17 5496219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM. C20 5496219P751 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM. C21 5494481P11 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM. C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C23 5496219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C24 19C300685P93 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EF Johnson 189. C25 5496219P7 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C26 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C27 5494481P11 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C28 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C27 549481P11 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C28 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: .001 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic d	Cl	19A116080P3	
C4 7491395P114 Ceramic disc: 0.0022 pf ±10%, 500 VDCW; sim to RMC Type JL.  C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW.  C6 19A116080P5 Polyester: 0.47 µf ±20%, 50 VDCW.  C7 7491395P111 Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RMC Type JL.  C8 5493367P1000K Silver mics: .001 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 5496419P71 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C19 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5496219P751 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C23 5496219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EF Johnson 189.  C24 19C300685P93 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EF Johnson 189.  C25 5496219P71 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM.  C26 5496219P71 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef 0 PPM.  C27 5496219P71 Ceramic disc: .001 pf ±0%, 1000 VDCW, temp coef 0 PPM.  C28 5496219P71 Ceramic disc: .001 pf ±0%, 500 VDCW, temp coef 0 PPM.  C29 5496219P71 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: .001 pf ±10%, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: .001 pf ±10%, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: .001 pf ±10%, 500 VDCW, temp coef 0 PPM.  C20 19C300685P93 Ceramic disc: .001 pf ±10%, 500 VDCW, temp coef 0 PPM.  C20 19C300685P93 Ceramic disc: .001 pf ±10%, 500 VDCW, temp coef 0 PPM.  C20	C2	19A116080P4	
to RMC Type JL.  Polyester: 0.1 µf ±20%, 50 VDCW.  Polyester: 0.47 µf ±20%, 50 VDCW.  Polyester: .047 µf ±20%, 50 VDCW.  Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RMC Type JL.  S493367P1000K  Silver mica: .001 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  Cli 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  Cla 19C300685P93  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  Cla 5494481P11  Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EM Johnson 189.  Cla 5491271P108  Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EM Johnson 189.  Cla 19C300685P93  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  Cla 19C300685P93  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  Cla 19C300685P93  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  Cla 5496219P751  Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C21 5496219P751  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C22 5491271P106  Caramic disc: .001 pf ±20%, 1000 VDCW; sim to EM Johnson 189.  C23 5496219P751  Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to EM Johnson 189.  C24 19C300685P93  Caramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751  Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C26 5496219P751  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 5496219P751  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 5496219P751  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 5496219P7  Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C29 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C27 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C28 5496219P7  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7  Ceramic	C3	19A116080P7	
C6 19A116080P5 C7 7491395P111 C8 7491395P111 C8 5493367P1000K C10 5491271P106 C10 5491271P106 C11 5496219P7 C12 19C300685P93 C13 5496219P7 C14 5496219P7 C15 5494481P111 C17 5496219P7 C18 19C300685P93 C19 5496219P7 C19 5496219P7 C10 5496219P7 C11 5496219P7 C12 5496219P7 C13 5496219P7 C14 5496219P7 C15 5494481P11 C15 5494481P11 C16 5491271P106 C17 5496219P7 C18 19C300685P93 C19 5496219P7 C19 5496219P7 C19 5496219P7 C19 5496219P7 C10 5496219P7 C10 5496219P7 C10 5496219P7 C11 5496219P7 C12 5496219P7 C13 19C300685P93 C14 5496219P7 C15 5496219P7 C16 5496219P7 C17 5496219P7 C18 19C300685P93 C19 5496219P7 C20 5496219P7 C20 5496219P7 C21 5496219P7 C22 5496219P7 C23 5496219P7 C24 19C300685P93 C25 5496219P7 C26 5496219P7 C27 5496219P7 C28 5496219P7 C29 5496219P7 C29 5496219P7 C20 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef .750 PPM. C21 C22 Ceramic disc: .001 pf ±20%, 1000 VDCW, temp coef .750 PPM. C22 5496219P7 C23 5496219P7 C24 19C300685P93 C25 C26 5496219P7 C26 5496219P7 C27 5494481P11 C28 5496219P7 C29 5496219P7 C29 5496219P7 C20 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef .750 PPM. C27 5496219P7 C28 5496219P7 C29 5496219P7 C29 5496219P7 C20 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef .750 PPM. C27 5496219P7 C28 5496219P7 C29 5496219P7 C29 5496219P7 C20 Ceramic disc: .301 pf ±10%, 1000 VDCW; sim to EF Johnson 189-6-5. C29 5496219P7 C20 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef .750 PPM. C27 5496219P7 C28 5496219P7 C29 5496219P7 C29 5496219P7 C20 5496219P7	C4	7491395P114	to RMC Type JL.
C7 7491395P111 Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RNC Type JL.  C8 5493367P1000K Silver mics: .001 pf ±10%, 100 VDCW; sim to Electro Motivo Type DM-20.  C10 549127IP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 and c13 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 549448IP111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 549127IP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 549448IP111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 549127IP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 549448IP111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 549127IP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C27 549448IP111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 549219P7 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 1800685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 1800685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 1800685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C5	19A116080P7	
to RMC Type JL.  Silver mica: .001 pf ilo%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C12 and c13 Ceramic disc: 33 pf io.1 pf, 500 VDCW, temp coef 0 PPM.  C14 5496219P751 Ceramic disc: .001 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C15 5494481P111 Ceramic disc: .001 pf io.5 pf, 500 VDCW; sim to EF Johnson 189.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 5 pf io.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: .001 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: .001 pf io.5 pf, 500 VDCW; sim to EF Johnson 189.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P7 Ceramic disc: 33 pf io.1 pf, 500 VDCW, temp coef 0 PPM.  C26 5496219P7 Ceramic disc: 33 pf io.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf io.1 pf, 500 VDCW, temp coef 0 PPM.  C28 5496219P7 Ceramic disc: 33 pf io.1 pf, 500 VDCW; sim to EF Johnson 189.  C29 5496219P7 Ceramic disc: .001 pf ilo%, 1000 VDCW; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C20 180300685P93 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C20 180300685P93 Ceramic disc: 7 pf io.5 pf, 500 VDCW, temp coef 0 PPM.  C20 180300685P93 Ceramic disc: 5 pf io.1 pf, 500 VDCW, temp coef 0 PPM.			
C10   5491271P106   Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.	C7	7491395P111	Ceramic disc: 0.0015 pf ±10%, 500 VDCW; sim to RMC Type JL.
Sim to EF Johnson 189.  C12	C8	5493367P1000K	Silver mica: .001 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.
Coef 0 PPM.  Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C13  C14 5496219P751	C10	5491271P106	Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.
Coef 0 PPM.  C14 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C15 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim temp coef .750 PPM.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 169.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef .750 PPM.  C21 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim temp coef .750 PPM.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C25 5496219P71 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim temp coef .750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef .750 PPM.  C30 19C300685P93 Ceramic disc: .5 pf ±0.1 pf, 500 VDCW, temp coef .750 PPM.	C11	5496219P7	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
-750 PPM.  Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to RF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.  C21 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to RF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481P111 Ceramic disc: .33 pf ±5%, 500 VDCW, temp coef .750 PPM.  C28 5496219P7 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5496219P7 Ceramic disc: .7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	and	19C300685P93	
RMC Type JF Discap.  Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C21 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P761 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C14	5496219P751	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.
Sim to EF Johnson 189.  C17	C15	5494481P111	Ceramic disc: .001 pf $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap.
Coef 0 PPM.  Cramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751	C16	5491271P106 :	Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.
coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C21 5494481P111 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481P111 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C17	5496219P7	
-750 PPM.  C21 5494481Pl11 Ceramic disc: .001 pf ±20%, 1000 VDCW; sim t BMC Type JF Discap.  C22 5491271Pl06 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481Pl11 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5491271Pl06 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	and	19C300685P93	
### Type JF Discap.    C22	C20	5496219P751	
Sim to EF Johnson 189.  C23 5486219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 and c25  C26 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C21	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C24 and C25 C26 C26 C27 C27 C28 C28 C29 C29 C29 C29 C29 C29 C29 C20 C29 C20 C20 C27 C27 C28 C28 C29	C22	5491271P106	Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.
coef 0 PPM.  C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481P111 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12,7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C23	5496219P7	
-750 PPM.  C27 5494481P111 Ceramic disc: .001 pf ±10%, 1000 VDCW; sim t RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	and	19C300685P93	Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.
C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C26	5496219P751	Cerawic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.
Sim to EF Johnson 189-6-5.  Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C27	5494481P111	Ceramic disc: .001 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C28	5491271P106	
C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C29	5496219P7	
		19C300685P93	Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp
Marie Company			

SYMBOL	GE PART NO.	DESCRIPTION
C32	5496219P751	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.
C33	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C34	5496372P50	Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef -2200 PPM.
C35	5496372P54	Ceramic disc: 270 pf ±5%, 500 VDCW, temp coef -2200 PPM.
C36	5496219P467	Ceramic disc: 150 pf ±5%, 500 VDCW, temp coef -220 PPM.
C37	5496372P327	Ceramic disc: 75 pf ±10%, 500 VDCW, temp coef -4700 PPM.
C38	5494481P131	Ceramic disc: .0068 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C39	5496372P145	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -3300 PPM.
C40	5496372P345	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -4700 PPM.
C41	5493366P180K	Silver mica: 180 pf ±10%, 100 VDCW; sim to
C44	5493366P470J	Electro Motive Type DM-15.  Silver mica: 470 pf ±5%, 100 VDCW; sim to
C45	5496372P45	Electro Motive Type DM-15,  Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -2200 PPM.
C46	5496372P347	Ceramic disc: 200 pf ±10%, 500 VDCW, temp coef
C47	5496219P749	-4700 PPM.  Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -750 PPM.
C48	5494481P129	Ceramic disc: .0039 pf ±20%, 1000 VDCW; sim to
C49	5494481P111	RMC Type JF Discap.  Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to
C50	5496219P253	RMC Type JF Discap.  Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.
C51	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
C52	5496219P253	-80 PPM.  Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.
C53	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.
C54 and C55	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C56	5496219P440	Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef -220 PPM.
C57	5496219P343	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -150 PPM.
C58	5491601P35	Phenolic: 0.15 pf ±10%, 500 VDCW.
C59	5493366P220K	Silver mica: 220 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.
C60	5496219P241	Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef -80 PPM.
C61	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -80 PPM.
C62	5496219P51	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.
C64	5494481P111	Ceramic disc: .001 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C65	5496219P35	Ceramic disc: 4 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
C66	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C67	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM.
C68	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C69	5496219P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
C70 thru C72	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
	3 72	

C73 C74 C75 C76 C77 CR1 and CR2 CR3 thru CR6 CV1 and CV2 J1 thru J17	5496267P18  19A115414P13 5494481P107 5493366P470K  5493366P270K  19A115250P1  19A115603P1  5495769P8  4033513P4  19B204526G2 19B204526G1	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D.  Polyester: 0.1 µf ±20%, 200 VDCW.  Ceramic dise: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  Silver mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  Silver mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.
C75 C76 C77 CR1 and CR2 CR3 thru CR6 CV1 and CV2 J1 thru J17	5494481P107 5493366P470K 5493366P270K 19A115250P1 19A115603P1 5495769P8 4033513P4	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  Silver mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  Silver mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  DIODES AND RECTIFIERS Silicon.  Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES Contact, electrical: sim to Bead Chain L93-3.
C76 C77 CR1 and CR2 CR3 thru CR6 CV1 and CV2 Jl thru J17	5493366P470K 5493366P270K 19A115250P1 19A115603P1 5495769P8 4033513P4	RMC Type JF Discap.  Silver mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  Silver mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  DIODES AND RECTIFIERS Silicon.  Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES Contact, electrical: sim to Bead Chain L93-3.
C77  CR1 and CR2 CR3 thru CR6 CV1 and CV2  J1 thru J17	5493366P270K  19A115250P1  19A115603P1  5495769P8  4033513P4  19B204526G2	Silver mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  Silver mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  DIODES AND RECTIFIERS Silicon.  Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES Contact, electrical: sim to Bead Chain L93-3.
CR1 and CR2 CR3 thru CR6 CV1 and CV2 J1 thru J17	19A115250P1 19A115603P1 5495769P8 4033513P4 19B204526G2	Silver mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.  DIODES AND RECTIFIERS Silicon.  Silicon.  Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES Contact, electrical: sim to Bead Chain L93-3.
and CR2 CR3 thru CR6 CV1 and CV2 J1 thru J17	19A115603P1 5495769P8 4033513P4 19B204526G2	Silicon.  Silicon.  Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.
and CR2 CR3 thru CR6 CV1 and CV2  J1 thru J17	19A115603P1 5495769P8 4033513P4 19B204526G2	Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES
thru CR6 CV1 and CV2 J1 thru J17	5495769P8 4033513P4 19B204526G2	Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.  JACKS AND RECEPTACLES
CV1 and CV2 J1 thru J17	4033513P4 19B204526G2	JACKS AND RECEPTACLES Contact, electrical: sim to Bead Chain L93-3.
thru J17	19B204526G2	Contact, electrical: sim to Bead Chain L93-3.
thru J17	19B204526G2	INDUCTORS
Ll		
	19B204526G1	
L2		Coil. Includes tuning slug 5491798P2.
L3 R1	19B204526G4 3R152P333J	Coil. Includes tuning slug 5491798P2. Composition: 33,000 ohms ±5%, 1/4 w.
L4 R1	19B204526G3 3R152P333J	Coil. Includes tuning slug 5491798P2. Composition: 33,000 ohms ±5%, 1/4 w.
L5	7488079P4B	Choke, RF: 27 µh ±10%, 1.4 ohms DC res max; #1
		to Jeffers 4422-9K.
Q1 and Q2	19A115123P1	Silicon, NPN; sim to Type 2N2712.
Q3 thru Q5	19A115330P1	Silicon, NPN.
Q6 and Q7	19A115328P1	/ Silicon, NPN.
Q8	19A115329P2	Silicon, NPN.
- to -	20	RESISTORS
R1	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R2	3R77P105K	Composition: 1 megohm ±10%, 1/2 w.
R3	3R77P472K	Composition: 4700 chms ±10%, 1/2 w.
R4	3R77P224K	Composition: 0.22 megohm ±10%, 1/2 w.
R5	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R6	3R77P684K	Composition: 0.68 megohm ±10%, 1/2 w.
R7	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R8	3R77P823K	Composition: 82,000 ohms ±10%, 1/2 w.
R9	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.
R10 and R11	3R77P274K	Composition: 0.27 megohm ±10%, 1/2 w.
R12*	19B209358P106	Variable, carbon film: approx 75 to 10,000 oh ±10%, 0.25 w; sim to CTS Type X-201.
		In Exciter 19D402308Gl thru G6 earlier than REV D; 19D402308G7 thru G12 earlier than REV E
	19B201969P6	Variable, carbon film: .01 megohm ±20%, 0.1 w sim to Centralab Series 4.
R13 and	3R77P224K	Composition: 0.22 megohm ±10%, 1/2 w.
R14 R15	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.
		200, 1/2 4

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL
R16	3R7/7P683K	Composition: 68,000 ohms ±10%, 1/2 w.	Т5
R17	3R77P823K	Composition: 82,000 ohms ±10%, 1/2 w.	
R18	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	
R19	3R77P222K	Composition: 2200 ohms ±10%, 1/2 w.	XY1 thr
R20	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	XY4
R 21	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	
R 22	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	
R23	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	
R24	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	Y1
R 25	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	thr Y4
R26	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	Y1
R27 and R28	3R17P153K	Composition: 15,000 ohms ±10%, 1/2 w.	thr Y4
R29	3R77P272K	Composition: 2700 ohms ±10%, 1/2 w.	
R30	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.	
R31	3R77P152K	Composition: 1500 ohms ±10%, 1/2 w.	0101
R32	3R 77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	C101
and R33 R34*	198209358P107	Variable, carbon film: approx 75 to 25,000 ohms	C104
KOX.	1552055567107	±10%, 0.25 w; sim to CTS Type X-201.	C105
		In Exciter 19D402308G1 thru G6 earlier than REV D; 19D402308G7 thru G12 earlier than REV E:	C106
	19\$201969P7	Variable, carbon film: .025 megohm ±20%, 0.1 w; sim to Centralab Series 4.	C107
R35	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	C108
R36	3R77P392K	Composition: 3900 ohms ±10%, 1/2 w.	
R37	3R 7P750J	Composition: 75 ohms ±5%, 1/2 w.	C109
R38	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	C110
R39	3R 7P620J	Composition: 62 ohms ±5%, 1/2 w.	0111
R40	3R77P181K	Composition: 180 ohms ±10%, 1/2 w.	Clli
R41 R42	3R77P470K 3R77P270K	Composition: 47 ohms ±10%, 1/2 w.  Composition: 27 ohms ±10%, 1/2 w.	C113
R43	3R 77P200J	Composition: 27 ohms ±10%, 1/2 w.  Composition: 20 ohms ±5%, 1/2 w.	C115
R44	3R77P223K	Composition: 22,000 ohms ±10%, 1/2 w.	
R45	3R7,7P153K	Composition: 15,000 ohms ±10%, 1/2 w.	C116
R46	194116278P474	Metal film: 0.576 megohm ±2%, 1/2 w.	C118
R47	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	
1 R48	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.	C119
R50	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.	C121
R53	3R 52P472K	Composition: 4700 ohms ±10%, 1/4 w.	and Cl22
		THERMISTORS	C125
RT1	198209284P6	Disc: 75 ohms, color code blue.	C126
RT3	193209284P2	Rod: 2140 ohms, color code red.	C127
RT5	193209284P6	Disc: 75 ohms, color code blue.	0121
RT7	19B209284P2	Rod: 2140 ohms, color code red.	C128
RT9	19820928496	Disc: 75 ohms, color code blue.	C130
RT11	198209284P2	Rod: 2140 ohms, color code red.	0130
RT13	193209284P6	Disc: 75 ohms, color code blue.	C132
RT15	193209284P2	Rod: 2140 ohms, color code red.	C135
		TRANSFORMERS	C136
Tl	193204534G1	Coil, Includes tuning slug 5491798P4.	C136
T2	19820453161	Coil. Includes tuning slug 5491798P4.	C138
тз	198204535G1	Coil. Includes tuning slug 5491798P4.	C140
Т4	19B204535G2	Coil. Includes tuning slug 5491798P4.	C140
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er 11 1		\$ 71 TH	
10			

GE PART NO.

19B204537Gl

19B206175P6

19B206175P7

5494481P12 5491271P6 5494481P12 19B209204P1 7489162P7 7489162P4

7489162P27

7489162P31

19B209204P1

5493392P7 19B209372P1

5493392P7 7489162PB

7489162P6

7489162P2

7489162P1

5494481P12

5493392P7 5490272P17

5493392P7 198209369P1 7489162P27 7489162P27 Refe

Wher exac Crys

Sil\* Ele

Sil Ele

Cer -47

Cer

Cer VDC

Sil Ele

Ref

Sil Ele

Cer RMC

Cer VDC

Cer

Sil Ele

\*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

12

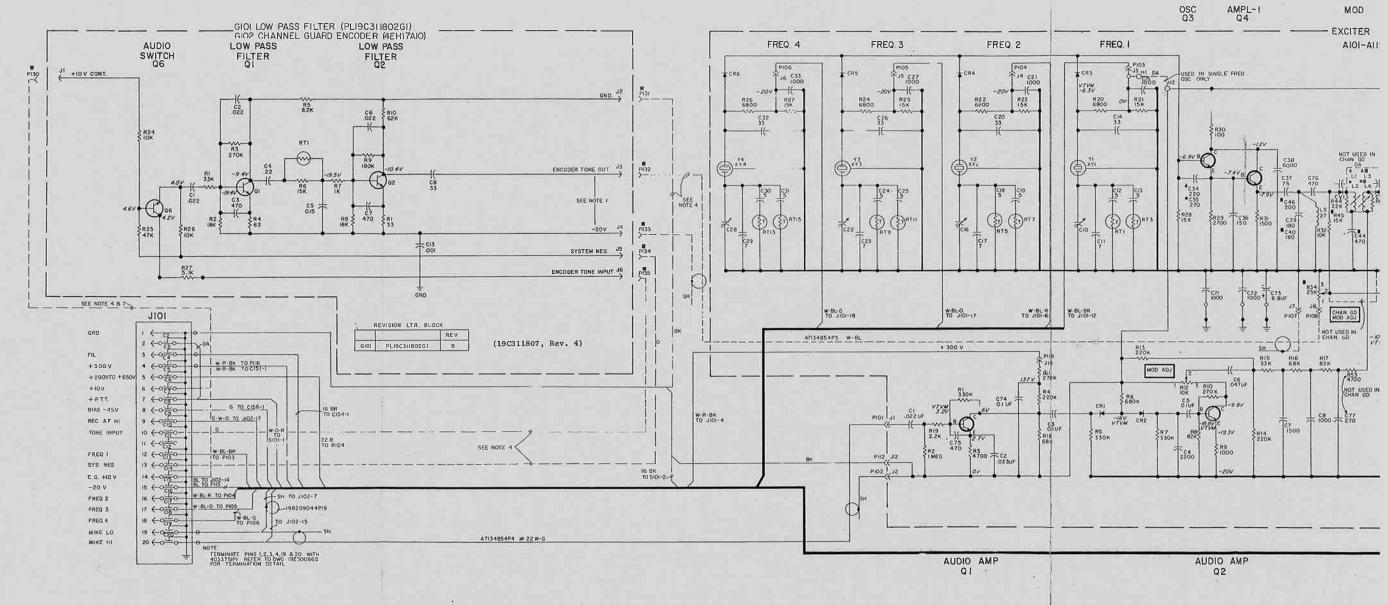
DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL
ncludes tuning slug 5491798P4,	C142	7485975P17	Ceramic, feed-thru: 470 pf ±20%, 750 VDCW; sim to Erie Style 327.	
SOCKETS	C143		Refer to Mechanical Parts (RC-1465 items 14,15).	R1
Mechanical Parts (RC-1465, items 1-4).	C144	¥	Refer to Mechanical Parts (RC-1465 items 25,26, 35).	R2 R3
	C145		Refer to Mechanical Parts (RC-1465 items 16-20).	R4
CRYSTALS	C147	5493392P7	Ceramic, feed-thru: .001 pf +100% -0%, 500	R5
rdering give GE Part Number and specify equency needed.	C148	5494481P12	VDCW; sim to Allen-Bradley Type FA5C.  Ceramic disc: .001 pf ±10%, 1000 VDCW; sim to	R6
frequency = (OF $\frac{1}{a}$ 36).	and C149		RMC Type JF Discap.	R7
freq range 11,000 to 12,566 KHz, temp °C to +85°C. (406-420 MHz Transmitter)	C150 thru C156	5493392P7	Ceramic, feed-thru: .001 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FASC.	R8 R9
freq range 12,500 to 14,500 KHz, temp 0°C to +85°C. (450-470 MHz Transmitter)	C157	198209282P1	Ceramic, feed-thru: 680 pf ±20%, 1000 VDCW; sim to Sprague Type 544C.	R10 R11
CHASSIS AND PA ASSEMBLY	C158 and C159	5493392P7	Ceramic, feed-thru: .001 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.	R24 R25
GUNIGYEON			DIODES AND RECTIFIERS	R26
CAPACITORS iisc: .001 pf ±10%, 1000 VDCW; sim to	CR101	4037822P1	Silicon.	R27
JF Discap.	CV101	19A115809P1	Silicon, capacitive.	
: approx 2.1-12.7 pf, 750 v peak; sim	= )			RT1
disc: .001 pf ±10%, 1000 VDCW; sim to JF Discap.	El	19B200535P3	Feed-thru: sim to Sealectro ST-1500SL-C3.	
disc: 220 pf ±10%, 500 VDCW, temp coef	E2	4029309Pl	Feed-thru: sim to Sealectro FT-SM-27.	
d. lca: 12 pf ±5%, 500 VDCW; sim to	E3	4036032P5	Feed-thru: sim to Sealectro FT-SM-10.	J101 J102
lotive Type DM-15.  .ca: 8 pf ±0.5 pf, 500 VDCW; sim to	E7	4034512P2	Feed-thru: sim to Sealectro FT-SM-22-TUR.	3102
otive Type DM-15.  ca: 100 pf ±5%, 500 VDCW; sim to otive Type DM-15.	Y.		BANDPASS FILTER	L101
ca: 150 pf ±5%, 500 VDCW; sim to			NOTE: The bandpass filters are factory tuned. If a filter component (except as shown	L102
otive Type DM-15. isc: 220 pf ±10%, 500 VDCW, temp coef			below) is found to be defective, it is recommended that the entire filter assembly be replaced to maintain rated power output and spurious attenuation.	L103
feed-thru: .001 pf +100% -0%; 500	FL101	19030355901	405~420 KHz.	L107
a to Allen-Bradley Type FA5C. approx 2.3 to 24.3 pf; sim to Dr Type V 193-0008-010.	FL102 G101	19C303559G2	450-470 MHz.	L108
feed-thru: .001 pf +100% -0%, 500	dioi		19C311802G1	L111
n to Allen-Bradley Type FA5C.				L112
Motive Type DM-15.	Cl	19A116080P103	Polyester: 0.022 µf ±10%, 50 VDCW.	L113
ica: 10 pf ±0.5 pf, 500 VDCW; sim to Wotive Type DM-15.	C2	19A116080P3	Polyester: 0.022 µf ±20%, 50 VDCW.	L115
Mechanical Parts (RC-1465 items 19, 31,	C3	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	1110
	C4	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.	L117
lca: 6 pf ±0.5 pf, 500 VDCW; sim to Wotive Type DM-15.	C5	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.	L119 and
.ca: 5 pf ±0.5 pf, 500 VDCW; sim to lotive Type DM-15.	C6	19A116080P3	Polyester: .022 µf ±20%, 50 VDCW.	L120
lisc: .001 pf ±10%, 1000 VDCW; sim to	C7	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L122
JF Discap.  feed-thru: .001 pf +100% -0%, 500 to Allen-Bradley Type FA5C.	C8	19B209243P14 5494481P111	Polyester: 0.33 µf ±20%, 250 VDCW.  Coramic disc: .001 pf ±10%, 1000 VDCW; sim to	L124 L125
: 2 to 7.83 pf, 1250 v peak; sim to			RMC Type JF Discap.	and L126 L127
feed-thru: .001 pf +100% -0%, 500 m to Allen-Bradley Type FASC.	J1 thru J6	4033513P4	Contact, electrical; sim to Bead Chain 193-3.	L128
650 pf ±20%, 400 VDCW; sim to EF Johnson 18.	0.0		TRANSISTORS	
ica: 100 pf ±5%, 500 VDCW; sim to Motive Type DM-15.	Q1	19A115123P1	Silicon, NPN; sim to Type 2N2712.	P101
ica: 100 pf ±5%, 500 VDCW; sim to	and Q2 Q6	19A115123P1		P102
ica: 100 pf ±5%, 500 VDCW; sim to Motive Type DM-15.	Q0	10011012391	Silicon, NPN; sim to Type 2N2712.	thru P106
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L113 19B205614P3 Coil.  L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10.  Part of can assembly 19B205625G1. Not recomended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 µm ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L122 7772834P7 Choke, RF: 0.2 µm ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z 124 19A121390P1 Coil.  L124 19A121390P1 Coil.  L125 and L126 19B205616P1 Coil.  L127 19B204658P3 Grid line.  L128 19B204658P1 Grid line.	SYMBOL	GE PART NO.	DESCRIPTION
R2 SR77P183K Composition: 18,000 ohms 1105, 1/2 w. R3 3R77P274K Composition: 0.27 megohm 1105, 1/2 w. R5 3R77P822K Composition: 8200 ohms 1105, 1/2 w. R6 3R77P822K Composition: 8200 ohms 1105, 1/2 w. R6 3R77P183K Composition: 1000 ohms 1105, 1/2 w. R7 3R77P183K Composition: 1000 ohms 1105, 1/2 w. R8 3R77P183K Composition: 1000 ohms 1105, 1/2 w. R8 3R77P183K Composition: 18,000 ohms 1105, 1/2 w. R8 3R77P184K Composition: 0.18 megohm 1105, 1/2 w. R11 3R77P33K Composition: 33 ohms 1105, 1/2 w. R12 3R77P103K Composition: 33 ohms 1105, 1/2 w. R24 3R77P103K Composition: 30,000 ohms 1105, 1/2 w. R25 3R77P473K Composition: 10,000 ohms 1105, 1/2 w. R26 3R77P103K Composition: 10,000 ohms 1105, 1/2 w. R27 3R77P512K Composition: 10,000 ohms 1105, 1/2 w. R27 3R77P512K Composition: 5100 ohms 1105, 1/2 w. R71 5490828P3O Composition: 5100 ohms 1105, 1/2 w. R71 5490828P3O Composition: 5100 ohms 1105, 1/2 w. R71 5490828P3O Composition: 5100 ohms 1105, 1/2 w. R71 192305489G1 Composition: 5100 ohms 1105, 1/2 w. R71 192305489G1 Composition: 5100 ohms 1105, 1/2 w. R71 192305489G1 Composition: 5100 ohms 1105, 1/2 w. R71 192305689G1 Composition: 5100 ohms 1105, 1/2 w.			RESISTORS
R3 3R77P274K Composition: 0.27 megohm filos, 1/2 w. R4 3R77P620J Composition: 62 ohms i55, 1/2 w. R5 3R77P620Z Composition: 8200 ohms i105, 1/2 w. R6 3R77P133K Composition: 15,000 ohms i105, 1/2 w. R7 3R77P134K Composition: 18,000 ohms i105, 1/2 w. R8 3R77P184K Composition: 18,000 ohms i105, 1/2 w. R8 3R77P184K Composition: 0,18 megohm i105, 1/2 w. R9 3R77P330K Composition: 6200 ohms i55, 1/2 w. R11 3R77P330K Composition: 6200 ohms i55, 1/2 w. R24 3R77P103K Composition: 33 ohms i105, 1/2 w. R25 3R77P473K Composition: 37 ohms i105, 1/2 w. R26 3R77P103K Composition: 10,000 ohms i105, 1/2 w. R27 3R77P512K Composition: 10,000 ohms i105, 1/2 w. R28 3R77P512K Composition: 5100 ohms i105, 1/2 w. R27 3R77P512K Composition: 5100 ohms i105, 1/2 w. R28 3R79P30K Composition: 5100 ohms i105, 1/2 w. R27 3R78512K Composition: 5100 ohms i105, 1/2 w. R28 3R79P31K Composition: 5100 ohms i105, 1/2 w. R29 3R79P512K Composition: 5100 ohms i105, 1/2 w. R20 1962054896	R1	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.
### R4	R2	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R5 3R77P822K Composition: 8200 ohms f10%, 1/2 w. R6 3R77P102K Composition: 15,000 ohms f10%, 1/2 w. R7 3R77P102K Composition: 15,000 ohms f10%, 1/2 w. R8 3R77P183K Composition: 18,000 ohms f10%, 1/2 w. R8 3R77P183K Composition: 18,000 ohms f10%, 1/2 w. R10 3R77P330K Composition: 6200 ohms f10%, 1/2 w. R11 3R77P330K Composition: 33 ohms f10%, 1/2 w. R24 3R77P103K Composition: 10,000 ohms f10%, 1/2 w. R25 3R77P103K Composition: 47,000 ohms f10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms f10%, 1/2 w. R27 3R77P512K Composition: 2100 ohms f10%, 1/2 w. R28 3R77P103K Composition: 2100 ohms f10%, 1/2 w. R29 3R77P512K Composition: 2100 ohms f10%, 1/2 w. R28 3R77P103K Composition: 2100 ohms f10%, 1/2 w. R28 3R77P103K Composition: 2100 ohms f10%, 1/2 w. R29 3R77P512K Composition: 2100 ohms f10%, 0.5 ohm DC res max sin to Jeffers 4412-9K. L101 198205615P1 Coil. L102 198205615P1 Coil. L111 198205614P2 Coil. L112 198205614P3 Coil. L113 198205614P3 Coil. L114 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. P2772834P7 Choke, RF: 0,2 µh f10%, 0.34 ohm f15% DC 320 WRS freq range; sin to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). L122 198205616P1 Coil. L123 198205616P1 Coil. L124 198121390P1 Coil. L125 198205616P1 Coil. L126 198205616P1 Coil. L127 198205616P1 Coil. L128 198205616P1 Coil. L129 198205616P1 Coil. L121 198205616P1 Coil. L122 198205616P1 Coil. L	R3	3R77P274K	Composition: 0.27 megohm ±10%, 1/2 w.
R6 3R77P153K Composition: 15,000 ohms ±10%, 1/2 w. R7 3R77P183K Composition: 1000 ohms ±10%, 1/2 w. R8 3R77P183K Composition: 15,000 ohms ±10%, 1/2 w. R9 3R77P184K Composition: 0.18 megohm ±10%, 1/2 w. R10 3R77P522J Composition: 0.18 megohm ±10%, 1/2 w. R11 3R77P330K Composition: 33 ohms ±10%, 1/2 w. R12 3R77P103K Composition: 10,000 ohms ±10%, 1/2 w. R24 3R77P103K Composition: 10,000 ohms ±10%, 1/2 w. R25 3R77P473K Composition: 10,000 ohms ±10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms ±10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms ±10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms ±10%, 1/2 w. R11 5490828P30 God: 0.33 megohm ±10% res, 1 w max; sim to Globar Type: 763H-3.	R4	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.
R7 3R77P102K Composition: 1000 ohms f105, 1/2 w. R8 3R77P183K Composition: 18,000 ohms f105, 1/2 w. R9 3R77P184K Composition: 0,18 megohm f105, 1/2 w. R10 3R77P22Z Composition: 6200 ohms f105, 1/2 w. R11 3R77P330K Composition: 33 ohms f105, 1/2 w. R24 3R77P330K Composition: 10,000 ohms f105, 1/2 w. R25 3R77P473K Composition: 10,000 ohms f105, 1/2 w. R26 3R77P103K Composition: 10,000 ohms f105, 1/2 w. R27 3R77P512K Composition: 5100 ohms f105, 1/2 w. R28 5490828P30 Rod: 0,33 megohm f105 res, 1 w max; sin to Globar Type 783H-3.  R29 198205689G1 Connector: 20 pin contacts.	R5	3R77P822K	Composition: 8200 ohms ±10%, 1/2 w.
R8 3R77P183K R9 3R77P184K R9 3R77P184K Composition: 0.18 megohm i10%, 1/2 w. Composition: 0.18 megohm i10%, 1/2 w. Composition: 0.200 ohms i5%, 1/2 w. R11 3R77P330K Composition: 33 ohms i10%, 1/2 w. R24 3R77P433K Composition: 10,000 ohms i10%, 1/2 w. R25 3R77P473K Composition: 47,000 ohms i10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms i10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms i10%, 1/2 w. Composition: 5100 ohms i10%, 1/2 w. R27 3R77P512K Composition: 10,000 ohms i10%, 1/2 w. R28 1000 ohms i10%, 1/2 w. R29 1000 ohms i10%, 1/2 w. R29 1000 ohms i10%, 1/2 w. R20 3R77P512K Composition: 10,000 ohms i10%, 1/2 w. R27 3R77P512K Composition: 10,000 ohms i10%, 1/2 w. R28 1000 ohms i10%, 1/2 w. R29 1000 ohms i10%, 1/2 w. R20 3R77P512K Composition: 20 ohms i10%, 1/2 w. R20	R6	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.
R9 3R77F184K Composition: 0.18 megohn ±10%, 1/2 w. R11 3R77P30K Composition: 6200 ohms ±10%, 1/2 w. R24 3R77P103K Composition: 0.000 ohms ±10%, 1/2 w. R25 3R77P473K Composition: 47,000 ohms ±10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms ±10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms ±10%, 1/2 w. R28 Composition: 5100 ohms ±10%, 1/2 w. R29 Composition: 5100 ohms ±10%, 1/2 w. R20 Composition: 47,000 ohms ±10%, 1/2 w. R20 Composition: 40,000 ohms ±10%, 1/2 w. R20 Com	R7	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.
R10 3R77P622J Composition: 6200 ohms i5%, 1/2 w. R11 3R77P330K Composition: 33 ohms i10%, 1/2 w. R24 3R77P103K Composition: 10,000 ohms i10%, 1/2 w. R25 3R77P473K Composition: 10,000 ohms i10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms i10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms i10%, 1/2 w. R28 Composition: 5100 ohms i10%, 1/2 w. R29 Composition: 5100 ohms i10%, 1/2 w. R29 Composition: 5100 ohms i10%, 1/2 w. R29 Composition: 5100 ohms i10%, 1/2 w. R20 Composition: 10,000 ohms i10%, 1/2 w. R20 Conposition: 10,000 ohms i10%, 1/2 w. R20 Conposition: 10,000 ohms i10%, 1/2 w. R20 Coil. R210	R8	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
### R24	R9	3R77P184K	Composition: 0.18 megohm ±10%, 1/2 w.
R24 3R77P103K Composition: 10,000 ohms 10%, 1/2 w. R25 3R77P473K Composition: 47,000 ohms 10%, 1/2 w. R26 3R77P103K Composition: 10,000 ohms 10%, 1/2 w. R27 3R77P512K Composition: 5100 ohms 110%, 1/2 w. R28 2R7	R10	3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.
R25 38.77P473K   Composition: 47,000 ohms ±10%, 1/2 w.   R26 38.77P103K   Composition: 10,000 ohms ±10%, 1/2 w.   R27 3R.77P512K   Composition: 5100 ohms ±10%, 1/2 w.   R28 2R.77P512K   Composition: 5100 ohms ±10%, 1/2 w.   R27 3R.77P512K   Composition: 5100 ohms ±10%, 1/2 w.   R28 2R.77P512K   Composition: 5100 ohms ±10%, 1/2 w.   R29 2R.77P512K   Composition: 5100 ohms ±10%, 1/2 w.   R20 2R.77P512K   R20 2	R11	3R77P330K	Composition: 33 ohms ±10%, 1/2 w.
R26 R27	R24	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
R27 3R77P512K Composition: \$100 chms ±10%, 1/2 w.	R25	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.
RT1 5490828P30 Rod: 0,33 megohm ±10% res, 1 w max; sim to Globar Type 783H-3.	R26	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
RT1 5490828P30 Rod: 0.33 megohm ±10% res, 1 w max; sim to Globar Type 783H-3.  JACKS AND RECEPTACLES J101 19C303426G1 Connector: 20 pin contacts.  J102 19B205689G1 Connector: 18 electrical contacts.  INDUCTORS L101 7488079P35 Choke, RF: 2,2 µh ±10%, 0.5 ohm DC res max sim to Jeffers 4412-9K.  L102 19A122524G2 Coil. L103 19A122524G1 Coil. L105 7488079P33 Choke, RF: 1 µh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.  L107 19B205615P2 Coil. L108 19B205615P1 Coil. L110 19B205614P2 Coil. L111 19B205614P3 Coil. L112 19B205614P3 Coil. L113 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. L116 Part of can assembly 19B205625G1. Not rec mended as a replaceable item. L117 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0	R27	3R77P512K	Composition: 5100 ohms ±10%, 1/2 w.
Rod: 0.33 megohm ±10% res, 1 w max; sim to Globar Type 783H-3.  JACKS AND RECEPTACLES J101 19C303426G1 Connector: 20 pin contacts.  J102 19B205689G1 Connector: 18 electrical contacts.  INDUCTORS L101 7488079P35 Choke, RF: 2,2 μh ±10%, 0.5 ohm DC res max sim to Jeffers 4412-9K.  L102 19A122524G2 Coil. L103 19A122524G1 Coil. L105 7488079P33 Choke, RF: 1 μh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.  L107 19B205615P2 Coil. L108 19B205615P1 Coil. L110 19B205614P2 Coil. L111 19B205614P3 Coil. L112 19B205614P4 Coil. L113 19B205614P3 Coil. L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. L116 Part of can assembly 19B205625G1. Not rec mended as a replaceable item. L117 7772834P7 Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). L122 7772834P7 Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10% to Ohmite Z Choke, RF: 0.2 μh ±10% to Ohmite Z Choke, RF: 0.2 μh			THERMISTORS
Globar Type 763H-3.	RT1	5490828P30	Rod: 0.33 megohm ±10% res. 1 w max; sim to
J101 19E305689G1 Connector: 20 pin contacts.  J102 19B205689G1 Connector: 18 electrical contacts.  Connector: 18 electrical contacts.  Choke, RF: 2,2 µh ±10%, 0.5 chm DC res may sim to Jeffers 4412-9K.  L103 19A122524G1 Coll.  L103 19A22524G1 Coll.  L104 19B205615P2 Coll.  L105 19B205615P2 Coll.  L106 19B205615P1 Coll.  L110 19B205614P2 Coll.  L111 19B205614P5 Coll.  L112 19B205614P4 Coll.  L113 19B205614P3 Coll.  L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10.  Part of can assembly 19B205625G1. Not rec mended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 µh ±10%, .034 chm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, 1tems 12, 13 and 23).  L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 chm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, 1tems 12, 13 and 23).  L122 19B205616P1 Coll.  L125 19B205616P1 Coll.  L126 19B205658P1 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P1 Contact, electrical: sim to AMP 41854.  P103 4029840P2 Contact, electrical: sim to AMP 42827-2.			Globar Type 783H-3.
J101 19E305689G1 Connector: 20 pin contacts.  J102 19B205689G1 Connector: 18 electrical contacts.  Connector: 18 electrical contacts.  Choke, RF: 2,2 µh ±10%, 0.5 chm DC res may sim to Jeffers 4412-9K.  L103 19A122524G1 Coll.  L103 19A22524G1 Coll.  L104 19B205615P2 Coll.  L105 19B205615P2 Coll.  L106 19B205615P1 Coll.  L110 19B205614P2 Coll.  L111 19B205614P5 Coll.  L112 19B205614P4 Coll.  L113 19B205614P3 Coll.  L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10.  Part of can assembly 19B205625G1. Not rec mended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 µh ±10%, .034 chm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, 1tems 12, 13 and 23).  L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 chm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, 1tems 12, 13 and 23).  L122 19B205616P1 Coll.  L125 19B205616P1 Coll.  L126 19B205658P1 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P1 Contact, electrical: sim to AMP 41854.  P103 4029840P2 Contact, electrical: sim to AMP 42827-2.			JACKS AND RECEPTACLES
L101 7488079P35 Choke, RF: 2.2 µh ±10%, 0.5 ohm DC res ma sim to Jeffers 4412-9K.  L102 19A122524G2 Coil.  L103 19A122524G1 Coil.  L105 7488079P33 Choke, RF: 1 µh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.  L107 19B205615P2 Coil.  L108 19B20561P2 Coil.  L110 19B205614P2 Coil.  L111 19B205614P3 Coil.  L112 19B205614P3 Coil.  L113 19B205614P3 Coil.  L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10.  Part of can assembly 19B205625G1. Not rec mended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L124 19A121390P1 Coil.  L125 19B205616P1 coil.  L126 19B204658P3 Grid line.  L127 19B204658P3 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P2 Contact, electrical: sim to AMP 42827-2.  L103 4029840P2 Contact, electrical: sim to AMP 42827-2.	J101	19C303426G1	Connector: 20 pin contacts.
L101 7488079P35 Choke, RF: 2,2 μh ±10%, 0.5 chm DC res masim to Jeffers 4412-9K.  L102 19A122524G2 Coil.  L103 19A122524G1 Coil.  L105 7488079P33 Choke, RF: 1 μh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.  L107 19B205615P2 Coil.  L108 19B205614P2 Coil.  L110 19B205614P5 Coil.  L111 19B205614P4 Coil.  L112 19B205614P4 Coil.  L113 19B205614P3 Coil.  L116 Part of can assembly 19B205625G1. Not recommended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 μh ±10%, 0.34 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L120 (Part of Mechanical Assembly, items 12, 13 and 23).  L121 19A121390P1 Coil.  L122 7772834P7 Choke, RF: 0.2 μh ±10%, 0.34 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L124 19A121390P1 Coil.  L125 19B205616P1 Coil.  L126 19B204658P3 Grid line.  L127 19B204658P3 Grid line.  L128 19B204658P1 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P1 Contact, electrical: sim to AMP 42827-2.	J102	19B205689G1	Connector: 18 electrical contacts.
L101 7488079P35 Choke, RF: 2,2 μh ±10%, 0.5 chm DC res masim to Jeffers 4412-9K.  L102 19A122524G2 Coil.  L103 19A122524G1 Coil.  L105 7488079P33 Choke, RF: 1 μh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.  L107 19B205615P2 Coil.  L108 19B205614P2 Coil.  L110 19B205614P5 Coil.  L111 19B205614P4 Coil.  L112 19B205614P4 Coil.  L113 19B205614P3 Coil.  L116 Part of can assembly 19B205625G1. Not recommended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 μh ±10%, 0.34 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L120 (Part of Mechanical Assembly, items 12, 13 and 23).  L121 19A121390P1 Coil.  L122 7772834P7 Choke, RF: 0.2 μh ±10%, 0.34 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L124 19A121390P1 Coil.  L125 19B205616P1 Coil.  L126 19B204658P3 Grid line.  L127 19B204658P3 Grid line.  L128 19B204658P1 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P1 Contact, electrical: sim to AMP 42827-2.			
L102 19A122524G2 Co11. L103 19A122524G1 Co11. L105 7488079P33 Choke, RF: 1 μh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K. L107 19B205615P2 Co11. L108 19B205614P2 Co11. L110 19B205614P5 Co11. L111 19B205614P4 Co11. L112 19B205614P3 Co11. L113 19B205614P3 Co11. L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. Part of can assembly 19B205625G1. Not rec mended as a replaceable item. L117 7772834P7 Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). L122 7772834P7 Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). L122 7772834P7 Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z Choke, RF: 0.2 μh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Oh			
L103	L101	7488079₽35	Choke, RF: 2,2 \(\mu\)h \(\pm\)10%, 0.5 ohm DC res max; sim to Jeffers 4412-9K.
Choke, RF: 1 μh ±10%, 0.15 ohm DC res max sim to Jeffers 4412-5K.	L102	19A122524G2	Coil.
Line	L103	19A122524G1	Coil.
Line	L105	7488079P33	Choke, RF: 1 µh ±10%, 0.15 ohm DC res max;
L108	1107	10P905615P2	
L110			
Lill 198205614P5 Coil. Lill 198205614P4 Coil. Lill 198205614P3 Coil. Lill 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. Part of can assembly 198205625G1. Not recommended as a replaceable item. Lill 7772834P7 Choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). Lill 27772834P7 Choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). Lill 28 198121390P1 Coil. Lill 25 198205616P1 Coil. Lill 26 198205616P1 Coil. Lill 27 198204658P3 Crid line. Lill 28 198204658P1 Grid line. Plo1 4029840P2 Contact, electrical: sim to AMP 42827-2. Plo2 4029840P1 Contact, electrical: sim to AMP 42827-2. Contact, electrical: sim to AMP 42827-2.			
Lil2 198205614P4 Coil. Lil3 198205614P3 Coil. Lil6 4036032P5 Feed-thru: sim to Sealectro FT-SM-10. Part of can assembly 198205625G1. Not recommended as a replaceable item. Lil7 7772834P7 Choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23). Lil22 7772834P7 Choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z choke, RF: 0.2 mh ±10%, .03			
L113 19B205614P3 Coil.  L115 4036032P5 Feed-thru: sim to Sealectro FT-SM-10.  Part of can assembly 19B205626G1. Not recomended as a replaceable item.  L117 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).  L120 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z 122 19A121390P1 Coil.  L121 19A121390P1 Coil.  L125 19B205616P1 Coil.  L126 19B204658P3 Grid line.  L127 19B204658P3 Grid line.  P101 4029840P2 Contact, electrical: sim to AMP 42827-2.  P102 4029840P2 Contact, electrical: sim to AMP 41854.  P103 4029840P2 Contact, electrical: sim to AMP 42827-2.		1	
Lilb			
Part of can assembly 198205625Gl. Not recomended as a replaceable item.			
mended as a replaceable item.		403003253	
S20 to 520 MHz freq range; sim to Ohmite Z (Part of Mechanical Assembly, items 12, 13 and 23).   Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z L124	P110		mended as a replaceable item.
Contact, electrical: sim to AMP 42827-2.	L117	7772834P7	
and 23). L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z L124 19A121390P1 Coil. L125 19B205616P1 Coil. L127 19B204658P3 Grid line. L128 19B204658P1 Grid line. Plo1 4029840P2 Contact, electrical: sim to AMP 42827-2. Plo2 4029840P1 Contact, electrical: sim to AMP 41854. Plo3 4029840P2 Contact, electrical: sim to AMP 42827-2.	1.119		(Part of Mechanical Assembly, items 12, 13, 22
L122 7772834P7 Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC 320 to 520 MHz freq range; sim to Ohmite Z L124 19A121390P1 Coil. L125 and L126 19B204658P3 Grid line. L128 19B204658P1 Grid line.  Pl01 4029840P2 Contact, electrical: sim to AMP 42827-2. Pl02 4029840P1 Contact, electrical: sim to AMP 41854. Pl03 4029840P2 Contact, electrical: sim to AMP 42827-2.	and		and 23).
320 to 520 MHz freq range; sim to Ohmite Z L124		7772834P7	Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC res,
L125 and L126 Coil. L127 198204658P3 Crid line. L128 198204658P1 Grid line.	1. 1		320 to 520 MHz freq range; sim to Ohmite Z-460
and L126			
L127	and	19B205616P1	Coil.
L128		- ango ( CE ppg	
P101 4029840P2 Contact, electrical: sim to AMP 42827-2. P102 4029840P1 Contact, electrical: sim to AMP 41854. P103 4029840P2 Contact, electrical: sim to AMP 42827-2.			
P101 4029840P2 Contact, electrical: sim to AMP 42827-2. P102 4029840P1 Contact, electrical: sim to AMP 41854. P103 4029840P2 Contact, electrical: sim to AMP 42827-2. thru	L128	19B204058F1	Grid line.
P102 4029840P1 Contact, electrical: sim to AMP 41854. P103 4029840P2 Contact, electrical: sim to AMP 42827-2.			
Pl03 4029840P2 Contact, electrical: sim to AWP 42827-2.	P101	4029840P2	Contact, electrical: sim to AMP 42827-2.
thru	P102	4029840P1	Contact, electrical: sim to AMP 41854.
		4029840P2	Contact, electrical: sim to AMP 42827-2.
P106	P106		
and the ball grade to the contract of			

SYMBOL	GE PART NO.	DESCRIPTION	SYM
P109 thru P113	4029840P2	Contact, electrical: sim to AMP 42827-2.	
P114	4029840P1	Contact, electrical: sim to AMP 41854.	
P115 thru P117	4029840P2	Contact, electrical: sim to AMP 42827~2.	1 2
	5	RESISTORS	3
R101	19All5416Pl	Precision, wirewound: 0.91 ohm ±1%, 2 w; sim to Dale Type RS-2B.	4 5
R102	19A115416P3	Precision, wirewound: 2.59 ohms ±1%, 2 w; sim to Dale Type RS-2B.	6
R103	3R77P330J	Composition: 33 ohms ±5%, 1/2 w.	7
R104	5493035P11	Wirewound: 40 ohms ±5%, 5 w; sim to Tru-Ohm Type X-60.	8
R105	3R77P393J	Composition: 39,000 ohms ±5%, 1/2 w.	9
R106	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	
R107	19A116278P444	Metal film: 0.28 megohm ±2%, 1/2 w.	10
R108	3R77P683J	Composition: 68,000 ohms ±5%, 1/2 w.	11
R109	3R79P273K	Composition: 27,000 ohms ±10%, 2 w.	12
R112	3R77P103J	Composition: 10,000 ohms 15%, 1/2 w.	13
R113	3R77P104J	Composition: 0.1 megohm ±5%, 1/2 w.	14
R114	3R77P681J	Composition: 680 ohms ±5%, 1/2 w.	15
R115	3R77P510J	Composition: 51 ohms ±5%, 1/2 w.	17
R117	3R149P223J	Composition: 22,000 ohms ±5%, 4 w.	18
R118	3R78P473K	Composition: 47,000 ohms ±10%, 1 w.	19
R120	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.	
R123	3R77P152K	Composition: 1500 ohms ±10%, 1/2 w.	20
R124	19B209381P1	Variable, composition: 10,000 ohms ±20%, 3 w; sim to Allen-Bradley Type K.	21
R125	3R149P153K	Composition: 15,000 ohms ±10%, 4 w.	22
R126	3R79P562K	Composition: 5600 ohms ±10%, 2 w.	23
R129	3R78P391J	Composition: 390 ohms ±5%, 1 w.	24
R130	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	25
			26
\$101	4031922P1	Pushbutton: SPST, normally open, 1/2 amp at 12 VDC; sim to Stackpole Type SS-15.	28*
		TERMINAL BOARDS	29*
TB1	7775500P9	Phen: 5 terminals.	
тв6	7775500P10	Phen: 4 terminals.	30
тв9	7487424P1	Miniature, phen: 1 terminal.	
TB10	7487424P2	Miniature, phen: 1 terminal.	
			31
V101		TUBES	32
V102		Type 8106.	33
V103		Type 8156. Type 8072.	34
		Type 8072.	35
		SOCKETS	36
XV101	7480532P8	Tube, phen: 9 pins; sim to Elco 04-903-84.	37
XV102	19C301007P5	Tube, plastic: 12 pins; sim to Alcon Metal Products 371G.	38
XV103	198209160P1	Tube, plastic: 11 pins; sim to EF Johnson 124-311-100.	39 40
- 1		TUNED CIRCUITS	
Z101 C1	19B204543G2 5496203P468	Coil, Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW, temp coef -5500 PPM.	41 42
Z102 C1	19B204543G1 5496203P468	Coil. Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW, temp coef -5600 PPM.	43*

4	SYMBOL	GE PART NO.	DESCRIPTION
			MECHANICAL PARTS (SEE RC-1465)
	1	19B200525P9	Rivet, (Part of XY1-4 in A101-112).
	2	19A115793P1	Contact, electrical: sim to Malco 2700. (Part of XY1-4 in Al01-112).
	3	19C311172P2	Socket. (Part of XY1-4 in A101-112).
1	4	4033089P1	Clip. (Part of XY1-4 in A101-112).
	5	19C311152P1	Heat sink.
ı	6	7165167P5	Insert, tube shield: sim to Atlas Insert 106-332-5. (Used with V101).
	7	19B204570P3	Heat sink, (Used with V101),
	8	19A122497P1	Support. (Used with V101).
	9	7165167₽9	Insert, tube shield: sim to Atlas Insert 106-332-21. (Used with V102).
	10	19A122497P2	Support. (Used with V102).
	11	19A122498P1	Heat sink. (Used with V102).
	12	19C311164P4	Plate line. (Used with L119).
	13	19C311164P5	Plate line. (Used with L119).
	14	19C311166P2	Base line. (Mounts L119, 120, Part of C143).
	15	19A121350P1	Insulator, (Part of C143),
	16	19A122526GI	Support. (Part of C145).
	17	19A122516P1	Slide. (Part of C145).
	18	19A122709P1	Set screw. 6-32. (Part of CI45).
	19	7117825P1	Washer, spring tension; sim to Tinnerman C4578B-632-24. (Part of C121, C122, C145).
1	20	19A122518G1	Spring. (Part of Cl45).
	21	19C303544P2	Cover. (Used with V103).
	22	19D402783P5	Plate line. (Used with L120).
	23	19C311164P6	Plate line. (Used with L120).
	24	19C303405P2	Casting. (Part of Cl21, Cl22).
1	25	4031593P1	Washer. (Part of C144).
	26	4032084P1	Washer, insulated. (Part of C144).
	27	19B204395G2	Chassis.
	28*	19B204393P1	Heat sink. (Used with Q8 in A101-A112). (Deleted from Exciter 19D402308G1 thru G6 by REV E, 19D402308G7 thru G12 by REV F.
	29*	19B204394P1	Support. (Used with Q8 in AlO1-All2). Deleted from Exciter 19D402308G1 thru G6 by REV E, 19D402308G7 thru G12 by REV F.
	30	19C303495G8	Station Top Cover. (Except Repeaters and VM).
		19C303673G3	Station Top Cover. (Repeaters and VM only).
		19C303396G1	Mobile Top Cover.
- 1	31	4036765G4	Set Screw. (Part of Cl21, Cl22).
	32	19A121676P1	Guide pin: 4-40 thread, (Used with J101).
	33	4036899P4	Insulator, standoff: sim to Centralab 3BX3778C. (Part of Cl21, Cl22).
	34	4036765G2	Screw. (Part of Cl21, Cl22).
	35	4031594P1	Insulator, (Part of Cl44).
	36	4036921P1	Bracket, angle: sim to Tinnerman C17609-8A-67.
	37	19B204366P1	Support.
100	38	4038930P1	Clip. (Mounts R104).
	39	4029030P10	Rubber Channel.
	40	19C3O3495G7	Station Bottom Cover.
	42	19C303396G3	Mobile Bottom Cover.
,	41	19A121065P1	(Not Used).
1	42	19A127257G1	(Not Used),
,	43*	4036555P1	Insulator, disc: nylon. (Added to Exciter 19940230861 thru GG by REV E, 19040230867 thru Gl2 by REV F.
3			
			5.1%



REANING ARE TYPICAL VOLTAGES MEASURED TO GROUND WITH A 20,000 OHM-PER-VOLT METER, WITH THE TRANSMITTER KEYED, AND WITH TUNE-OPERATE SWITCH IN THE OPERATE POSITION. PA PLATE VOLTAGES WILL WARY AS SHOWN IN THE FOLLOW-MO

PA PLATE VOLTAGE ET-59-D ET-60-D		PA IMPUT	RATED	APPLICATION	POWER SUPPLY
290 VDC		60 WATTS	20 WAT TS	P.A. EXCITER OR CLASS A, C. B. STATION OR MOBILE	4EP37AIO 4EP38AIO
380 VDC		70 WATTS	20 WATTS	6-VOLT MOBILE	4EP37CIO
435 VDC			90 WATTS 35 WATTS	12-VOLT MOBILE	4EP37810
430 VUC	3.5	90 WATTS		28-VOLT MOBILE	4EP37010
	485 VDC	120 WATTS	40 WATTS	STATION	4FP38AIO
- 1	660 VDC	EO VICE 180 WATTS	70 WATTS	MOBILE	4EP37A10
	DOC APC	150 WATTS	SO WATTS	STATION	4EP38AIO -

READINGS SHOWN ON QI AND Q2 ON GIOI/GIO2 WERE MEASURED IN A NEGATIVE GROUND SYSTEM, FOR POSITIVE GROUND SYSTEMS, MEASURE QI AND Q2 READINGS TO J5 ISYSTEM NEGATIVE) ON GIOI/GIO2.

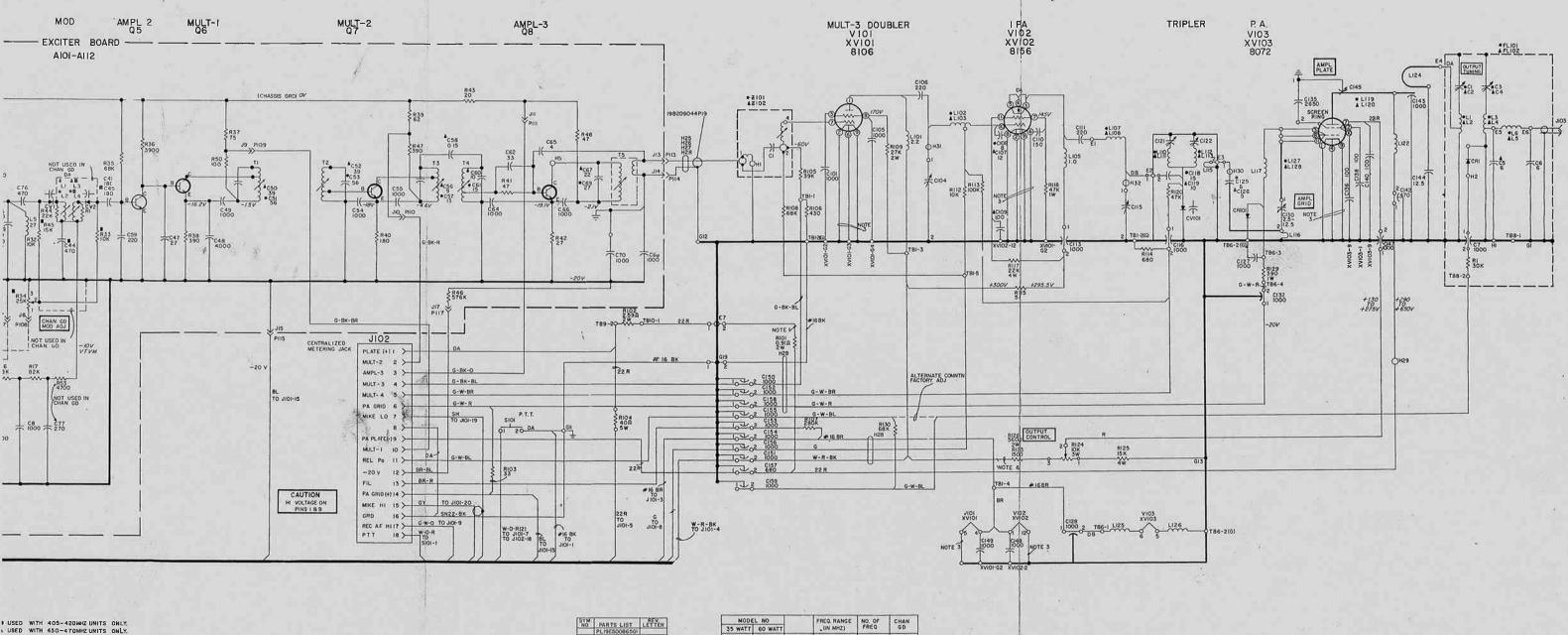
(19R621283, Rev. 1)

● USED WITH 405-420MHZ ▲ USED WITH 450-470MHZ ■ USED WITH CHAN GD UN

NOTES

L RIOI USED IN 4ET59D MC WITH DA WIRE ON 4ET 2 ALL 22R WIRES ARE A40 3. BEND TERMINAL BACK

<sup>5-</sup> ALL WIRES N22 EXCEPT / 6- R123 USED IN 4ET60D M WITH R126 ON 4ET59D 7- CONNECTED TO PIN 6 ON CONNECTED TO PIN 14 ON



5. ALL WIRES N22 EXCEPT AS OTHERWISE SHOWN.
6. RI23. USED IN 4 ETSOD MODELS ONLY, 9123 IS REPLACED WITH RIZE ON 4ET590 MODELS.
7. CONNECTED TO PIN 6 ON MODELS 36, 8 37.
CONNECTED TO PIN 10 ON MODELS 38,39,40 B 41.

NO	PARTS LIST	LETTER
	PL19E500865G1	
down	PL19E500865G2	
AIOI	PL19D402308GI	E
AIO2	PL19D40230862	E
A103	PL19040230803	E
AIO 4	PL190402308G4	E .
AIQ5	PLI9040230805	E
AIQ 6	PL19D402308G6	E
AIO7	PLI9040230807	F
AlO8	PL/9040230968	F
Al09	PLI9040230869	F
AllO	PL190402306G0	F
AIII	PL19D4023066II	F
All2	PL19D40230802	F
		-

MODEL NO		FREQ. RANGE	NO. OF	CHAN
35 WATT	60 WATT	_UN MHZ)	FREQ	GD
4ET59030	4E160030	405-420	1	
4ET59D31"	4ET60031	450-470	1	
4ET59032	4ET60D32	405-420	2	
4ET59033	4ET60033	450-470	2	
4ET59034	4ET60034	405-420	4	
4ET59035	4ET60035	450-470	4	
4ET59036	4ET60036	405-420		×
4ET59037	4ET60037	450-470		X
4ET59038	4ET60038	405-420	2	X
4ET59039	4ET60039	450-470	2	X
4ET59040	4ET60040	405-420	4	X
4ET59041	4ET60041	450-470	1 4	X

## **SCHEMATIC DIAGRAM**

406-470 MHz, 35 & 60-WATT MASTR TRANSMITTER MODELS 4ET59D30-41 & MODELS 4ET60D30-41

## **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

#### CHANNEL GUARD LOW PASS FILTER GIO1

Rev. A & B - Incorporated into initial shipment

#### EXCITER BOARD A101-A112 (19D412308G1 thru G12)

Rev. A thru C - 19D402308G1 thru G6 Rev. A thru D - 19D402308G7 thru G12

Incorporated into initial shipments.

Rev. D - 19D402308G1 thru G6 Rev. E - 19D402308G7 thru G12

To improve stability and facilitate adjustment of modulation limiting and Channel Guard levels. Changed R12 and R34.

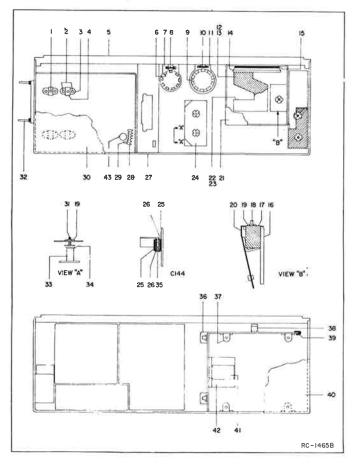
Rev. E - 19D402308G1 thru G6 Rev. F - 19D402308G7 thru G12

To facilitate manufacturing. Deleted the heat sink and mechanical parts to mount Q8. Added parts to mount Q8 on the board.

#### CHASSIS & PA ASSEMBLY

Rev. A - 19E500865G1 & G2

To improve assembly. Changed items 12,13,14,22 and 23 of mechanical Parts List.



4ET59DIO-41 4ET60DIO-41

## PARTS LIST

LBI-3936D

CHANNEL GUARD ENCODER G102 4EH17A10 19C311802-G2

SYMBOL	GE PART NO.	DESCRIPTION
C1*	19B209243-P103	Polyester: 0.022 μf ±10%, 50 VDCW.
	19B209243-P2	Earlier than REV A: Polyester: 0.015 $\mu$ f $\pm 20\%$ , 50 VDCW.
C2	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
C3	5494481-Pl07	Ceramic disc: $470$ pf $\pm 20\%$ , $1000$ VDCW; sim to RMC Type JF Discap.
C4	19B209243-P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C5	19B209243-P8	Polyester: 0,15 $\mu$ f $\pm 20\%$ , 50 VDCW.
C6	19B209243-P3	Polyester: 0.022 μf ±20%, 50 VDCW.
C7	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
CB	19B209243-P14	Polyester: 0.33 µf ±20%, 250 VDCW.
C9	5496267-P1	Tantalum: 6.8 µf ±20%, 6 YDCW; sim to Sprague Type 150D.
C10	19B209243-P117	Polyester: 0.22 µf ±10%, 50 VDCW.
C11 thru C13	5494481-P111	Ceramic disc: .001 $\mu f$ ±20%, 1000 VDCW; sim to RMC Type JF Discap.
		DIODES AND RECTIFIERS
CR1 and CR2	19A115250-P1	Silicon.
FL1		TONE FREQUENCY NETWORK 198205280
	198205280-02 198205280-03 198205280-04 198205280-06 198205280-06 198205280-06 198205280-06 198205280-06 198205280-01 198205280-01 198205280-01 198205280-01 198205280-01 198205280-01 198205280-01 198205280-01 198205280-02 198205280-02 198205280-02 198205280-02 198205280-02 198205280-02	77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Ez 103.5 Hz 107.2 Hz 111.8 Hz 121.3 Hz 131.8 Hz 131.8 Hz 131.8 Hz 131.8 Hz 131.8 Hz 131.8 Hz 141.3 H
J1 thru J6	4033513-124	Contact, electrical; sim to Bead Chain L93-3.
Q1 and Q2	19A115123-P1	Silicon, NPN; sim to Type 2N2712.
Q3 thru Q5	19Al15362~Pl	Silicon, NPN; sim to Type 2N2925.
		RESISTORS
R1	3R77-P333K	Composition: 33,000 ohms ±10%, 1/2 w.
B2	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.

<sup>\*</sup>COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
R3	3R77-P274K	Composition: 0.27 megohms ±10%, 1/2 w.
R4	3R77-P620J	Composition: 62 ohms ±5%, 1/2 w.
R5	3R77-P822K	Composition: 8200 ohms ±10%, 1/2 w.
R6	3R77-P153K	Composition: 15,000 ohms ±10%, 1/2 w.
R7	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
R8	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R9	3R77-P184K	Composition: 0.18 megohms ±10%, 1/2 w.
R10	3R77-P622J	Composition: 6200 ohms ±5%, 1/2 w.
R11	эк77-рээок	Composition: 33 ohms ±10%, 1/2 w.
R12	5495948-P365	Deposited carbon: 46,400 ohms $\pm 1\%$ , 1/2 w; sim to Texas Instrument CD1/2MR.
R13	3R77-P682J	Composition: 6800 ohms ±5%, 1/2 w.
R14	3R77-P244J	Composition: 0.24 megohms ±5%, 1/2 w.
R15	19A116278-P233	Metal film: 2150 ohms ±2%, 1/2 w.
R16	19A116278-P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R17	19A116278-P65	Metal film: 46.4 ohms $\pm 2\%$ , $1/2$ w.
R18	19A116278-P329	Metal film: 19,600 ohms $\pm 2\%$ , $1/2$ w.
R19	19A116278-P285	Metal film: 7500 ohms $\pm 2\%$ , $1/2$ w.
R20	19A116278-P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R21	19A116278-P269	Metal film: 5110 ohms $\pm 2\%$ , $1/2$ w.
R22	19A116278-P117	Metal film: 147 ohms $\pm 2\%$ , 1/2 w.
R23	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
RT1	5490828-P30	Thermistor: 330,000 ohms $\pm 10\%$ , color code black and gray; sim to Globar Type 783H-3.
RT2	5490828-P36	Thermistor: 55,000 ohms $\pm 10\%$ , color code black and red; sim to Globar Type 723B.
Wl		(Part of XFL1),
XFL1	19A121920-G3	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/4 inches of cable.
		ENCODER INSTALLATION KIT 19A127174-G1
		MISCELLANEOUS
	N404P13C13	Lockwasher, no. 6.
	N 80 Pl 3005 Cl 3	Machine screw, no. $6-32 \times 5/16$ .
	19B201074-P304	Tap screw, no. 6-32 x 1/4.
	N210P13C13	Nut, no. 6-32.
	19B205480-G2	Harness. Includes:
P130 thru P135	4029840-P2	Contact, electrical; sim to Amp 42827-2.

## **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - To improve Channel Guard low pass filter. Changed Cl.

## ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- GE Part Number for component
   Description of part
   Model number of equipment

- 4. Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

## **MAINTENANCE MANUAL**

LBI-3998

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ● LYNCHBURG, VIRGINIA 24502

